



SGM2537A

4A, 35mΩ eFuse with Selectable Over-Voltage Clamping Function

GENERAL DESCRIPTION

The SGM2537A family is a compact electronic fuse (eFuse) with circuit protection functions, which can be used as a solution to power management. The FET hot-swap device is also highly integrated in a small package. With very few external components, the SGM2537A can provide multiple protection modes. To encounter overloads, voltage surges, short-circuits and high inrush current, the device is suitable as a robust defense.

A single external resistor can be used to set the output current limit, and after detecting the voltage drop across the resistor, it is possible to monitor the load current accurately. Also, a single external capacitor is enough to set the output slew rate for applications with particular inrush current requirements. Using internal clamping circuits alone can quickly limit over-voltage events to a fixed maximum value within a safe range. The SGM2537A-PRN variant provides an option to set a user-defined over-voltage cutoff threshold.

The SGM2537A is available in a Green TDFN-2×2-8AL package.

FEATURES

- Input Voltage: 2.7V to 18V, Surge up to 20V
- Low On-Resistance: 35mΩ (TYP)
- Output Clamp Response Time: 5μs (TYP)
- Programmable Current Limit: 0.5A to 4A
- ±7.5% Current Limit Accuracy
- Load Current Monitor Output
- Quick Output Discharge (SGM2537A-xRD)
- Programmable Soft-Start Time (SS)
- Over-Temperature Protection (OTP)
- Fault Flag (nFAULT Pin)
- UL Recognized Component (File No. E532373*)
- Available in a Green TDFN-2×2-8AL Package

APPLICATIONS

Hot-Swap and Hot-Plug
Adapter Power Devices
SSD and HDD Drives
Set-Top Boxes
Printers
White Goods
Digital TVs

SELECTABLE MODEL

Model	Output Clamp Voltage (V)	Thermal Shutdown	Enable	Quick Output Discharge
SGM2537A-3.8L	3.8	Latch-Off	High	-
SGM2537A-3.8R	3.8	Auto-Retry	High	-
SGM2537A-3.8RD	3.8	Auto-Retry	High	Yes
SGM2537A-5.7L	5.7	Latch-Off	High	-
SGM2537A-5.7R	5.7	Auto-Retry	High	-
SGM2537A-5.7RD	5.7	Auto-Retry	High	Yes
SGM2537A-5.7RN	5.7	Auto-Retry	Low	-
SGM2537A-13.7L	13.7	Latch-Off	High	-
SGM2537A-13.7R	13.7	Auto-Retry	High	-
SGM2537A-UL	Unavailability	Latch-Off	High	-
SGM2537A-UR	Unavailability	Auto-Retry	High	-
SGM2537A-PRN	Programmable Over-Voltage Lockout	Auto-Retry	Low	-

PACKAGE/ORDERING INFORMATION

MODEL	PACKAGE DESCRIPTION	SPECIFIED TEMPERATURE RANGE	ORDERING NUMBER	PACKAGE MARKING	PACKING OPTION
SGM2537A-3.8L	TDFN-2×2-8AL	-40°C to +125°C	SGM2537A-3.8LXTDE8G/TR	1E6 XXXX	Tape and Reel, 3000
SGM2537A-3.8R	TDFN-2×2-8AL	-40°C to +125°C	SGM2537A-3.8RXTDE8G/TR	1E7 XXXX	Tape and Reel, 3000
SGM2537A-3.8RD	TDFN-2×2-8AL	-40°C to +125°C	SGM2537A-3.8RDXTDE8G/TR	1E8 XXXX	Tape and Reel, 3000
SGM2537A-5.7L	TDFN-2×2-8AL	-40°C to +125°C	SGM2537A-5.7LXTDE8G/TR	1E9 XXXX	Tape and Reel, 3000
SGM2537A-5.7R	TDFN-2×2-8AL	-40°C to +125°C	SGM2537A-5.7RXTDE8G/TR	1EA XXXX	Tape and Reel, 3000
SGM2537A-5.7RD	TDFN-2×2-8AL	-40°C to +125°C	SGM2537A-5.7RDXTDE8G/TR	1EB XXXX	Tape and Reel, 3000
SGM2537A-5.7RN	TDFN-2×2-8AL	-40°C to +125°C	SGM2537A-5.7RNXTDE8G/TR	1EC XXXX	Tape and Reel, 3000
SGM2537A-13.7L	TDFN-2×2-8AL	-40°C to +125°C	SGM2537A-13.7LXTDE8G/TR	1ED XXXX	Tape and Reel, 3000
SGM2537A-13.7R	TDFN-2×2-8AL	-40°C to +125°C	SGM2537A-13.7RXTDE8G/TR	1EE XXXX	Tape and Reel, 3000
SGM2537A-UL	TDFN-2×2-8AL	-40°C to +125°C	SGM2537A-ULXTDE8G/TR	1EF XXXX	Tape and Reel, 3000
SGM2537A-UR	TDFN-2×2-8AL	-40°C to +125°C	SGM2537A-URXTDE8G/TR	1EG XXXX	Tape and Reel, 3000
SGM2537A-PRN	TDFN-2×2-8AL	-40°C to +125°C	SGM2537A-PRNXTDE8G/TR	1EH XXXX	Tape and Reel, 3000

MARKING INFORMATION

NOTE: XXXX = Date Code, Trace Code and Vendor Code.

Y Y Y — Serial Number
X X X X

Green (RoHS & HSF): SG Micro Corp defines "Green" to mean Pb-Free (RoHS compatible) and free of halogen substances. If you have additional comments or questions, please contact your SGMICRO representative directly.

ABSOLUTE MAXIMUM RATINGS

Pin Voltage Range

IN	-0.3V to 20V
OUT	-0.3V to $V_{IN} + 0.3V$
EN/UVLO	-0.3V to 7V
nFAULT (SGM2537A-xx/xRN)	-0.3V to 7V
QOD Pin Voltage (SGM2537A-xRD), V_{QOD}	-0.3V to 7V
Output Voltage Pulse ($< 1\mu s$), V_{OUT_PLS}	$> -1.2V$
SS Pin Voltage, V_{SS}	6V
nFAULT Pin Sink Current, I_{nFAULT}	10mA
Maximum Continuous Switch Current	Internally Limited

Package Thermal Resistance

TDFN-2x2-8AL, θ_{JA}	78°C/W
Junction Temperature	+150°C
Storage Temperature Range	-65°C to +150°C
Lead Temperature (Soldering, 10s)	+260°C

ESD Susceptibility

HBM	4000V
CDM	1000V

RECOMMENDED OPERATING CONDITIONS

Pin Voltage Range

IN	2.7V to 18V ⁽¹⁾
OUT	0V to $V_{IN} + 0.3V$
EN/UVLO	0V to 6V ⁽²⁾
nFAULT (SGM2537A-xx/xRN)	0V to 6V
QOD (SGM2537A-xRD)	0V to 6V

Continuous Output Current

$T_J = -40^\circ C$ to $+125^\circ C$, I_{MAX}	4A
$T_J = -40^\circ C$ to $+105^\circ C$, I_{MAX}	5A ⁽³⁾

Resistance of ILIM Pin (Limiting Output Current), R_{ILIM}	487Ω to 5000Ω
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SS Capacitor Value, C_{SS}	$> 3300pF$
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SS Pin Capacitor Voltage Rating, V_{SS}	$> 5V$
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Operating Junction Temperature, T_J	-40°C to +125°C
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NOTES:

1. It is recommended to limit the nominal input voltage according to the output clamp voltage.
2. When supply voltages are below 6V, the EN/UVLO and IN pins can be connected directly. When supply voltages exceed 6V, a suitable resistor divider should be used from IN, EN/UVLO to GND pin. This resistor is used to guarantee that the EN/UVLO pin voltage is within the set limits.
3. Guaranteed by design, not by tests at production.

OVERSTRESS CAUTION

Stresses beyond those listed in Absolute Maximum Ratings may cause permanent damage to the device. Exposure to absolute maximum rating conditions for extended periods may affect reliability. Functional operation of the device at any conditions beyond those indicated in the Recommended Operating Conditions section is not implied.

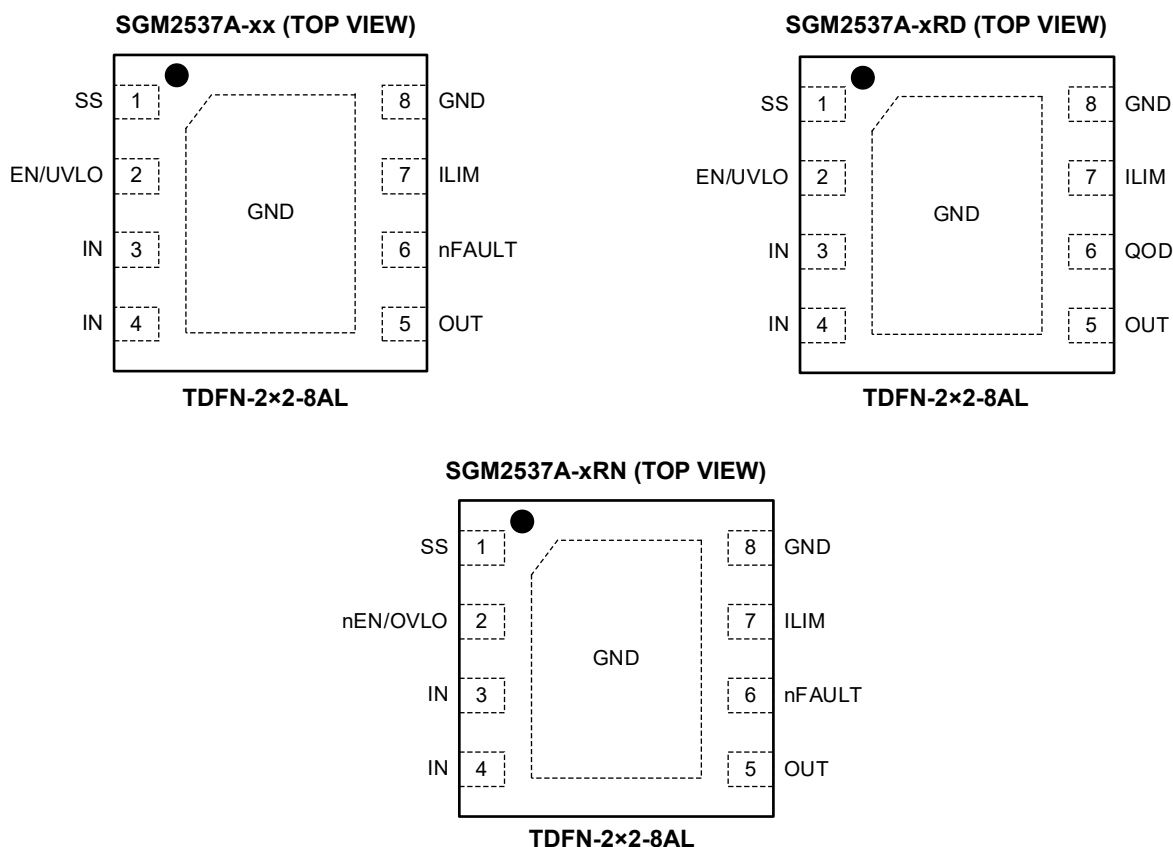
ESD SENSITIVITY CAUTION

This integrated circuit can be damaged if ESD protections are not considered carefully. SGMICRO recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage. ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because even small parametric changes could cause the device not to meet the published specifications.

DISCLAIMER

SG Micro Corp reserves the right to make any change in circuit design, or specifications without prior notice.

PIN CONFIGURATIONS



PIN DESCRIPTION

PIN	NAME	TYPE	FUNCTION
1	SS	Analog I/O	Soft-Start Pin. Connecting a capacitor to GND can set the output turn-on slew rate. Float this pin for the maximum slope of turn on slew rate.
2	EN/UVLO	Analog Input	Enable and Under-Voltage Lockout Input. SGM2537A-xx/xRD Only. Active-high logic-enable for the device. Use a resistor divider to set programmable under-voltage lockout threshold. Do not float this pin.
	nEN/OVLO		Enable and Over-Voltage Lockout Input. SGM2537A-xRN Only. Active-low logic-enable for the device. Use a resistor divider to set programmable over-voltage lockout threshold. Do not float this pin.
3, 4	IN	Power	Input Supply Voltage.
5	OUT	Power	Output of the Device.
6	nFAULT	Digital Output	Alert Open-Drain Output Pin. SGM2537A-xx/xRN Only. When detecting a fault, this fault event indicator will be pulled low. An external $R_{PULL-UP}$ is needed for this open-drain output.
	QOD		Quick Output Discharge Pin. SGM2537A-xRD Only. Tied to OUT directly or through external resistor.
7	ILIM	Analog I/O	Current Limit Programming Pin. Use this dual function pin for limiting and monitoring the output current. Connecting this pin to GND can set the output current limit. It is also possible to monitor the load current with this pin voltage. Do not float this pin.
8	GND	Ground	Ground.
Exposed Pad	GND	Thermal/Ground	Connect to GND.

ELECTRICAL CHARACTERISTICS

($T_J = -40^{\circ}\text{C}$ to $+125^{\circ}\text{C}$, $V_{IN} = 12\text{V}$ for SGM2537A-13.7x/Ux/PRN, $V_{IN} = 5\text{V}$ for SGM2537A-5.7x/5.7RD/5.7RN, $V_{IN} = 3.3\text{V}$ for SGM2537A-3.8x/3.8RD, $V_{EN} = 5\text{V}$ (0V for SGM2537A-xRN only), $R_{ILIM} = 1000\Omega$, $C_{SS} = \text{Open}$, $\text{OUT} = \text{Open}$, typical values are at $T_J = +25^{\circ}\text{C}$, unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS		MIN	TYP	MAX	UNITS
Input Supply (IN)							
Input Voltage Range	V _{IN}			2.7		18	V
Under-Voltage Protection Threshold	V _{UVP}	V _{IN} Rising		2.46	2.55	2.64	V
		V _{IN} Falling		2.24	2.32	2.40	
Supply Quiescent Current	I _Q	SGM2537A-xx/SGM2537A-xRD: V _{EN} ≥ V _{UVLO}			148	220	μA
		SGM2537A-xRN: V _{EN} ≤ V _{OVLO}					
Supply Shutdown Current	I _{SD}	SGM2537A-xx/SGM2537A-xRD : V _{EN} < 0.5V	V _{IN} ≤ 5V		0.25		μA
			5V < V _{IN} ≤ 18V		0.73	5.00	
		SGM2537A-xRN: V _{EN} > 2V			39	70	
On-Resistance (IN - OUT)							
On-Resistance	R _{ON}	V _{IN} = 5V to 18V	T _J = +25°C		35		mΩ
			T _J = -40°C to +85°C			65	mΩ
			T _J = -40°C to +125°C			70	mΩ
		V _{IN} = 2.7V to 5V	T _J = +25°C		40		mΩ
			T _J = -40°C to +85°C			70	mΩ
			T _J = -40°C to +125°C			80	mΩ
Output Voltage Clamp (OUT)							
Over-Voltage Clamp Threshold	V _{OVC}	SGM2537A-3.8x/3.8RD	V _{IN} Rising, R _{OUT} = 10kΩ	3.70	3.90	4.10	V
		SGM2537A-5.7x/5.7RD/5.7RN		5.53	5.72	5.90	V
		SGM2537A-13.7x		13.30	13.70	14.30	V
Output Voltage while Clamping	V _{CLAMP}	SGM2537A-3.8x/3.8RD	V _{IN} ≥ V _{OVC} , I _{OUT} = 10mA	3.40	3.60	3.80	V
		SGM2537A-5.7x/5.7RD/5.7RN		5.20	5.45	5.70	V
		SGM2537A-13.7x		13.00	13.60	14.10	V
Output Clamp Response Time	t _{OVC}	SGM2537A-3.8x/5.7x/13.7x/ 3.8RD/5.7RD/5.7RN	I _{OUT} = 4A		5		μs
			I _{OUT} = 100mA		10		μs
Output Current Limit and Monitor (ILIM)							
ILIM Pin Current Monitor Gain (I _{ILIM} /I _{OUT})	G _{IMON}	I _{OUT} = 4A, T _J = -40°C to +125°C		240	280	320	μA/A
		I _{OUT} = 2A, T _J = -40°C to +125°C		242	276	310	
		I _{OUT} = 1A, T _J = -40°C to +125°C		245	273	302	
I _{OUT} Current Limit	I _{LIMIT}	R _{ILIM} = 487Ω, T _J = -40°C to +125°C		3.60	4.10	4.60	A
		R _{ILIM} = 1000Ω, T _J = -40°C to +125°C		1.80	2.04	2.28	
		R _{ILIM} = 1780Ω, T _J = -40°C to +125°C		1.09	1.17	1.24	
		R _{ILIM} = 4420Ω, T _J = -40°C to +125°C		0.39	0.49	0.58	
		R _{ILIM} = Open			0		

ELECTRICAL CHARACTERISTICS (continued)

($T_J = -40^{\circ}\text{C}$ to $+125^{\circ}\text{C}$, $V_{IN} = 12\text{V}$ for SGM2537A-13.7x/SGM2537A-Ux, $V_{IN} = 5\text{V}$ for SGM2537A-5.7x/5.7RD/5.7RN, $V_{IN} = 3.3\text{V}$ for SGM2537A-3.8x/3.8RD, $V_{EN} = 5\text{V}$, $R_{ILIM} = 1000\Omega$, $C_{SS} = \text{Open}$, $\text{OUT} = \text{Open}$, typical values are at $T_J = +25^{\circ}\text{C}$, unless otherwise noted.)

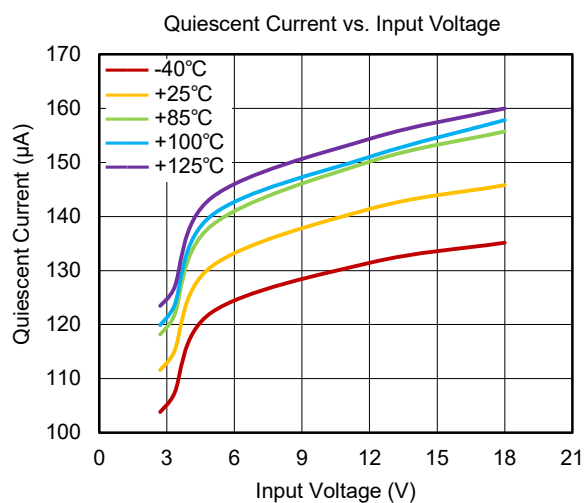
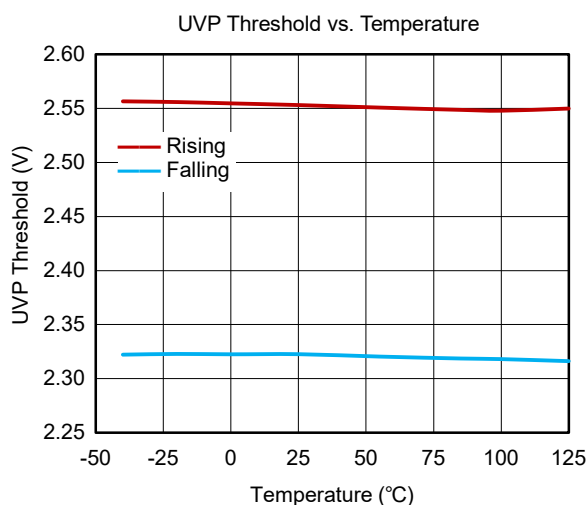
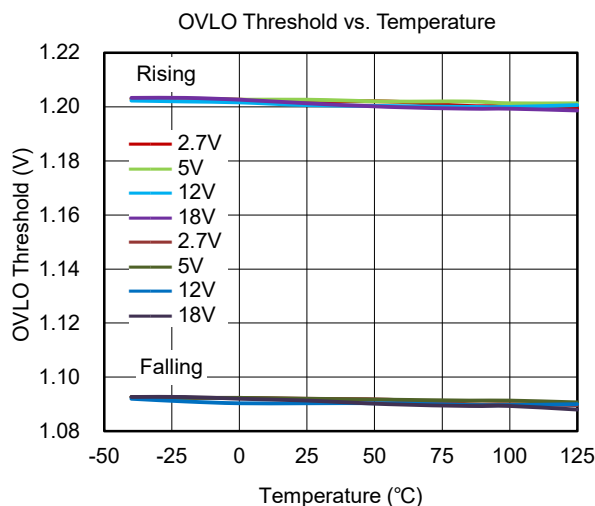
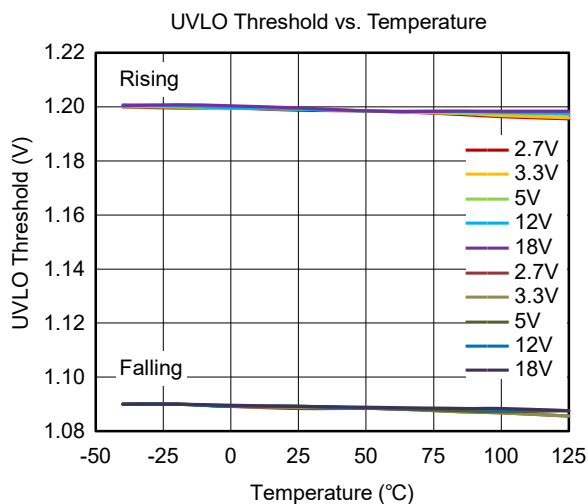
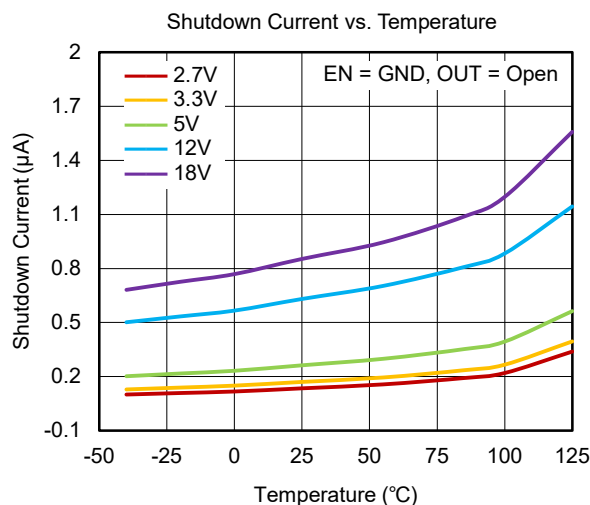
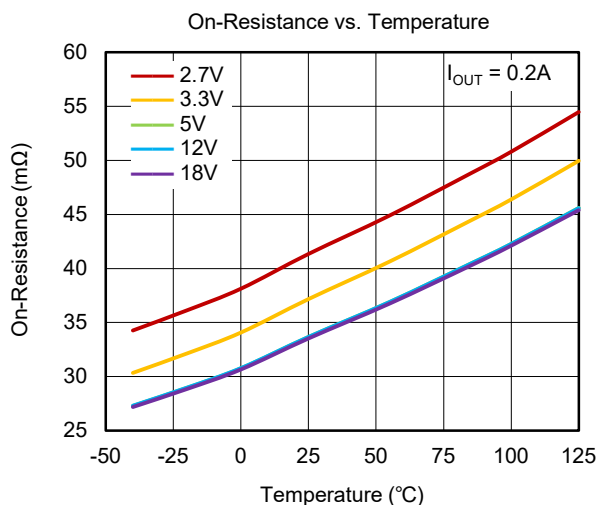
PARAMETER	SYMBOL	CONDITIONS		MIN	TYP	MAX	UNITS
I _{OUT} Circuit Breaker Threshold during R _{ILIM} Short Condition	I _{CB}	R _{ILIM} = Short to GND			1.8		A
Current Limit Response Time	t _{LIM}	I _{OUT} > I _{LIMIT} + 20% × I _{LIMIT} to I _{OUT} ≤ I _{LIMIT}			250		μs
Short-Circuit Response Time	t _{SC}	I _{OUT} > I _{SC} to I _{OUT} ≤ I _{LIMIT}			5		μs
Enable/Under-Voltage Lockout (EN/UVLO) (SGM2537A-xx/xRD)							
EN/UVLO Leakage Current	I _{EN}	V _{EN} = 5V		-2.5		2.5	μA
Under-Voltage Lockout Threshold	V _{UVLO_R}	V _{EN} rising		1.13	1.20	1.27	V
	V _{UVLO_F}	V _{EN} falling		1.03	1.10	1.17	
nEnable/Over-Voltage Lockout (nEN/OVLO) (SGM2537A-xRN)							
nEN/OVLO Pin Leakage Current	I _{EN}			-2.5		2.5	μA
Over-Voltage Lockout Threshold	V _{OVLO_R}	V _{EN} rising		1.13	1.20	1.27	V
	V _{OVLO_F}	V _{EN} falling		1.03	1.10	1.17	
Over-Voltage Lockout Response Time	t _{OVLO}	V _{EN} > V _{OVLO} to nFAULT ↓			3		μs
Fault Indication (nFAULT) (SGM2537A-xx/xRN)							
nFAULT Resistance	R _{nFAULT}	nFAULT ↓, I _{SINK} = 1mA, test V _{nFAULT}			13		Ω
nFAULT Leakage Current	I _{nFAULT}	V _{EN} = 2V, V _{nFAULT} = 6V		-2.5		2.5	μA
Quick Output Discharge (QOD) (SGM2537A-xRD)							
QOD Effective Resistance	R _{QOD}	IN connected to EN, OUT connected to QOD, EN ↓ to 1V			15		Ω
Over-Temperature Protection (OTP)							
Thermal Shutdown Temperature	T _{SD}	T _J rising			156		°C
Thermal Shutdown Hysteresis	T _{HYS}	T _J falling			15		°C
Thermal Shutdown Auto-Retry Interval	t _{TSD_RST}	SGM2537A-xR/xRD/xRN: enabled and T _J < T _{SD} - T _{HYS}	2.7V < V _{IN} ≤ 3.3V		72		ms
			3.3V < V _{IN} ≤ 5V		85		ms
			5V < V _{IN} ≤ 18V		110		ms

SWITCHING CHARACTERISTICS

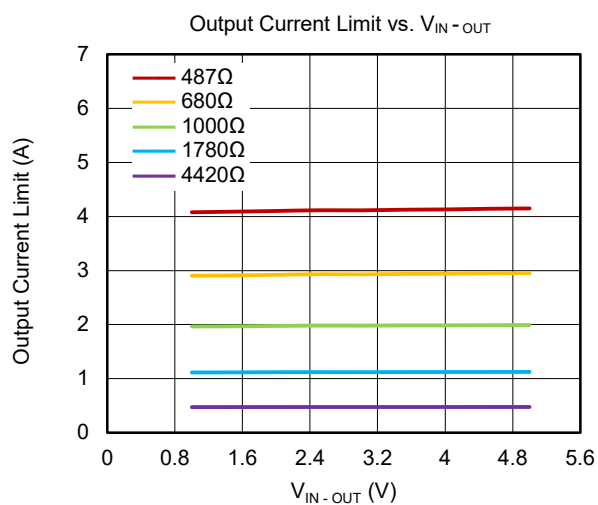
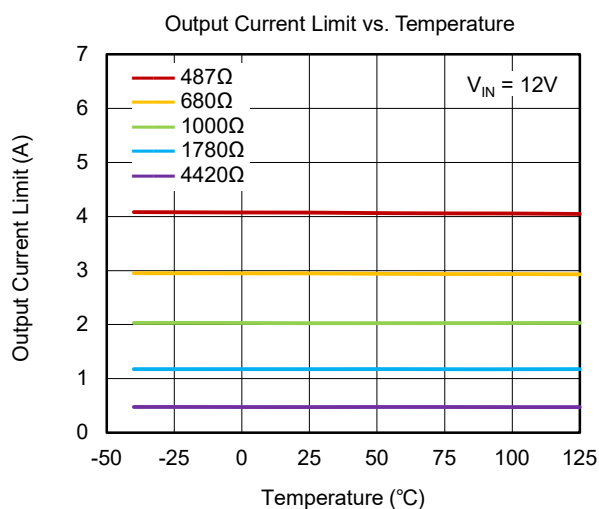
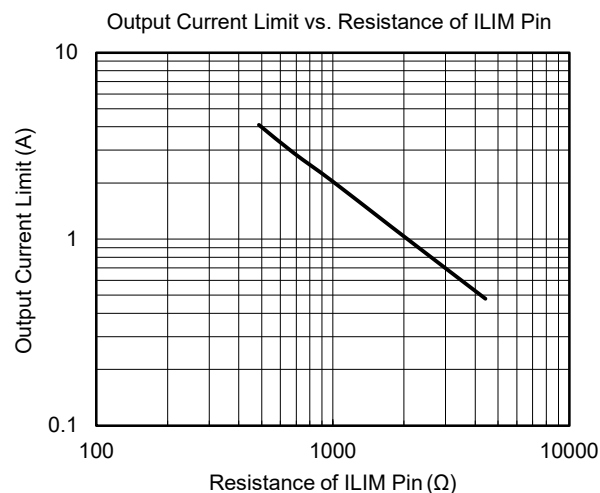
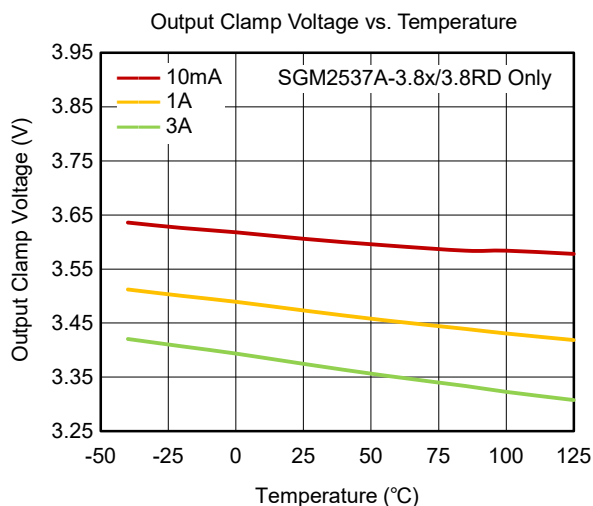
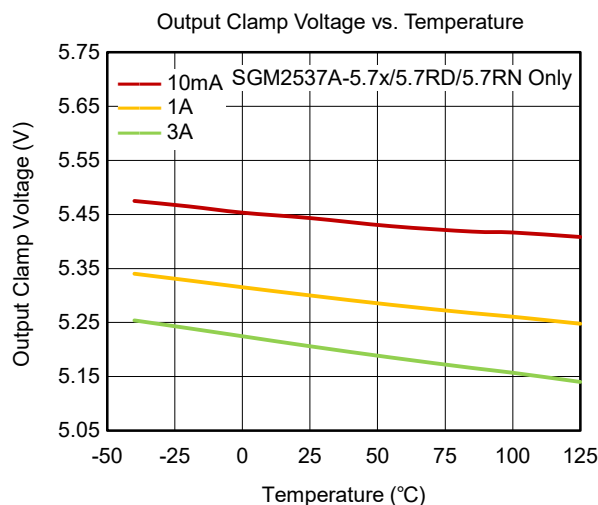
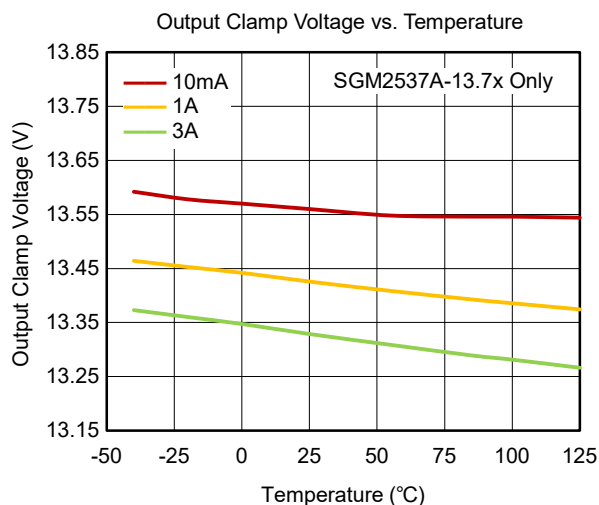
($R_{OUT} = 100\Omega$, $C_{OUT} = 1\mu\text{F}$, typical values are at $T_J = +25^{\circ}\text{C}$, unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS	$C_{SS} = \text{Open}$	$C_{SS} = 3300\text{pF}$	UNITS
Output Rising Slew Rate	SR_{ON}	$V_{IN} = 3.3\text{V}$	30	10	V/ms
		$V_{IN} = 5\text{V}$	40	10	
		$V_{IN} = 12\text{V}$	85	10	
Turn-On Delay	t_{D_ON}	$V_{IN} = 3.3\text{V}$	125	180	μs
		$V_{IN} = 5\text{V}$	130	202	
		$V_{IN} = 12\text{V}$	130	280	
Rise Time	t_R	$V_{IN} = 3.3\text{V}$	88	270	μs
		$V_{IN} = 5\text{V}$	100	390	
		$V_{IN} = 12\text{V}$	112	925	
Turn-Off Delay	t_{D_OFF}	$V_{IN} = 3.3\text{V}$	10.5	10.5	μs
		$V_{IN} = 5\text{V}$	9.6	9.6	
		$V_{IN} = 12\text{V}$	6.5	6.3	

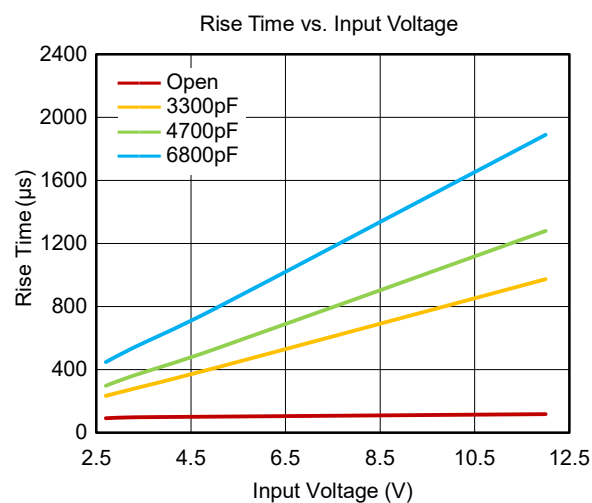
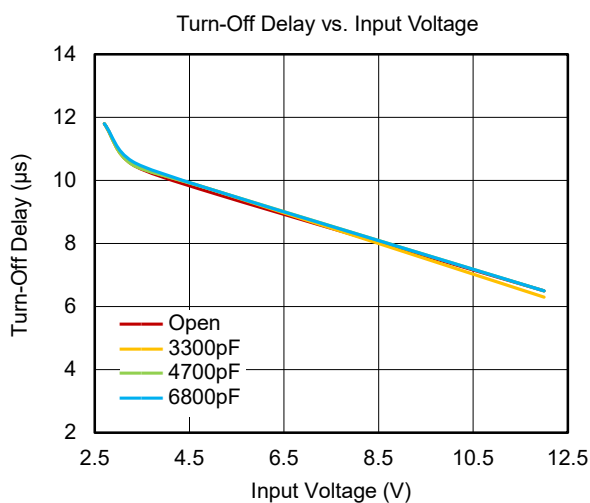
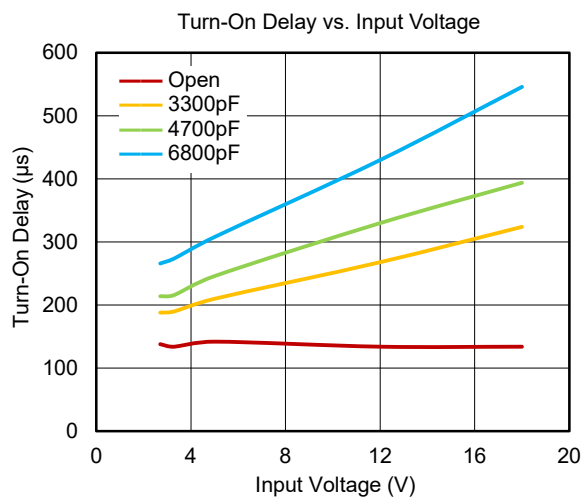
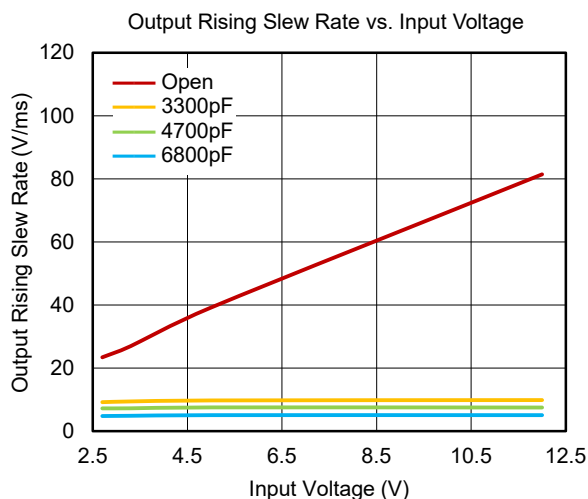
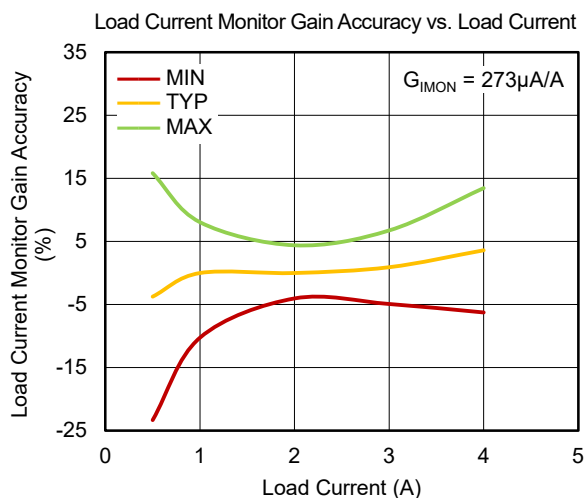
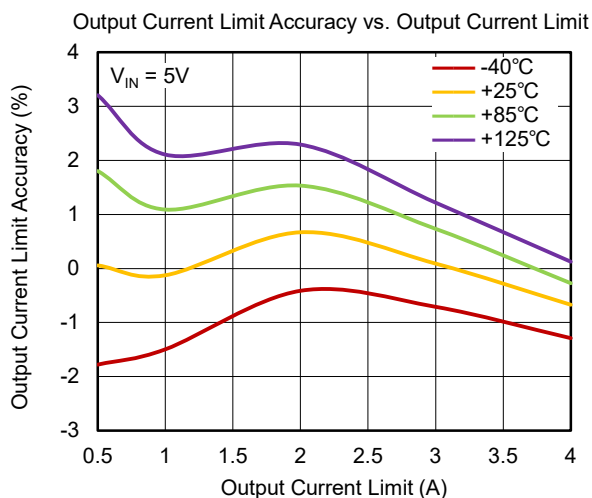
TYPICAL PERFORMANCE CHARACTERISTICS



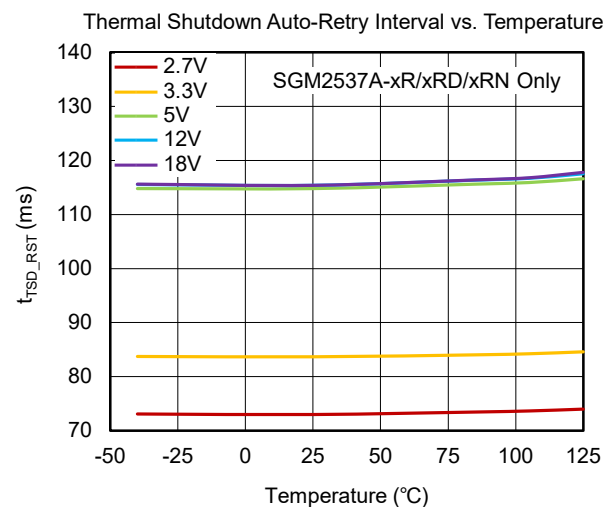
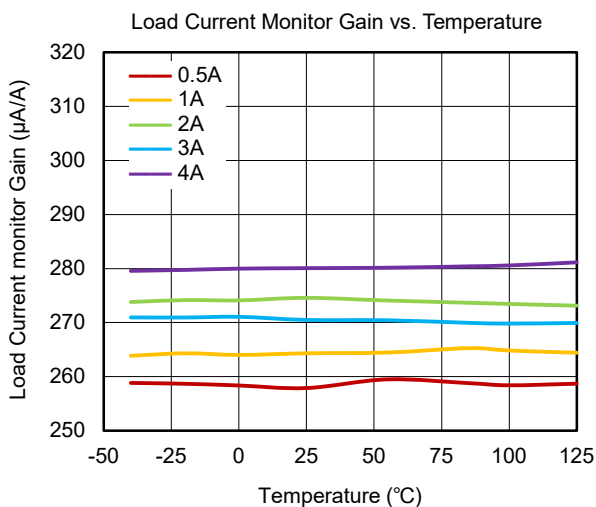
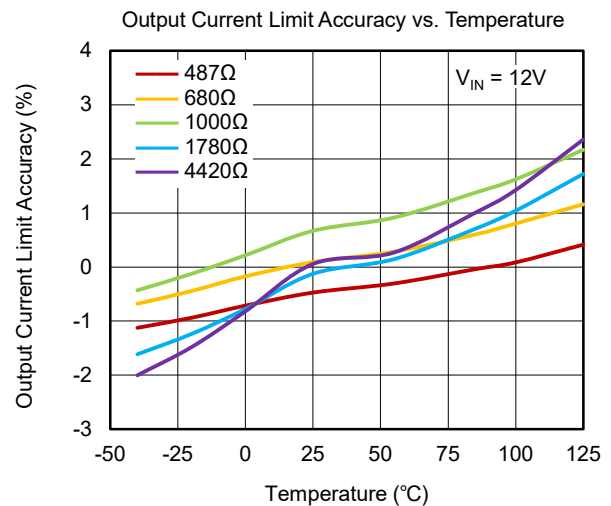
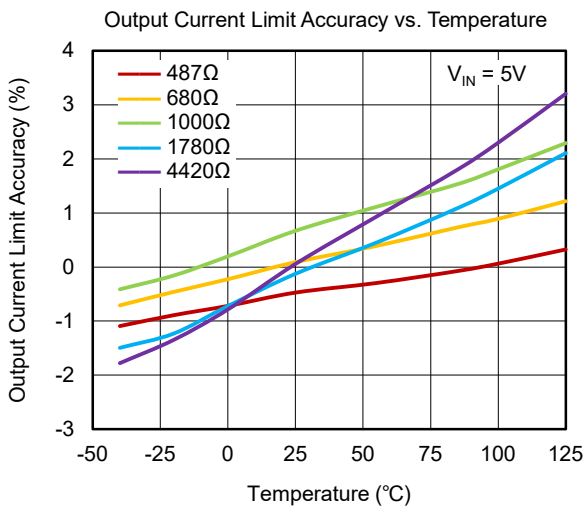
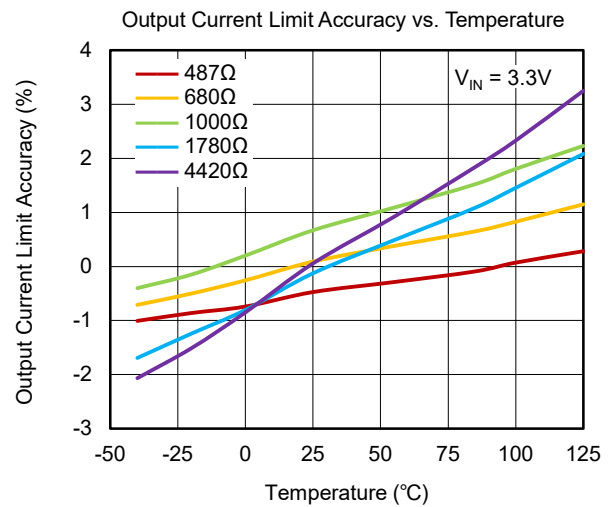
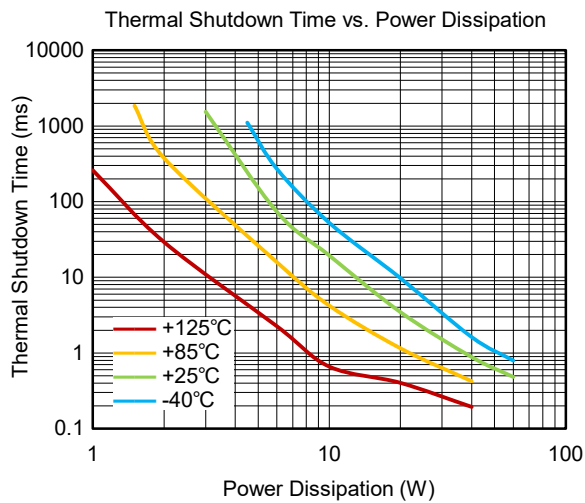
TYPICAL PERFORMANCE CHARACTERISTICS (continued)



TYPICAL PERFORMANCE CHARACTERISTICS (continued)



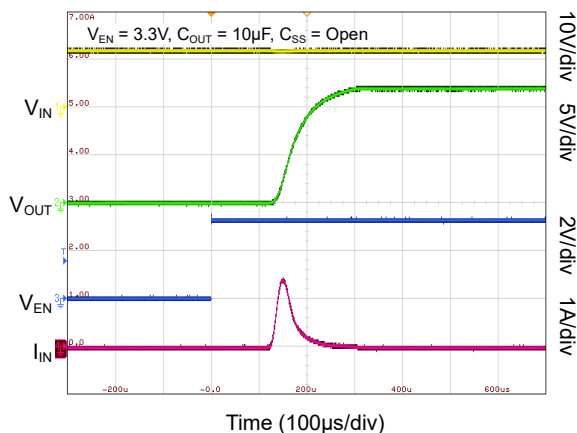
TYPICAL PERFORMANCE CHARACTERISTICS (continued)



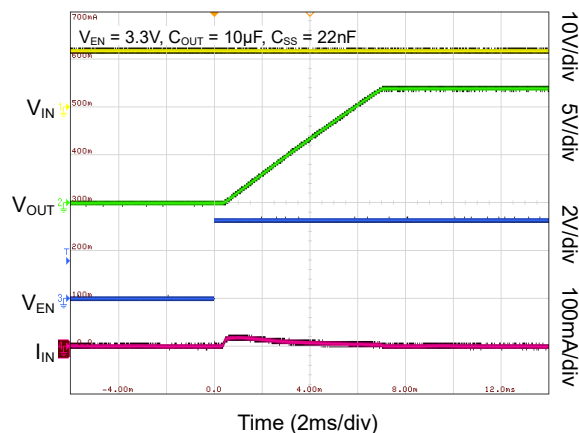
TYPICAL PERFORMANCE CHARACTERISTICS (continued)

 $T_A = +25^\circ\text{C}$, $V_{IN} = 12\text{V}$, $R_{ILIM} = 487\Omega$, unless otherwise noted.

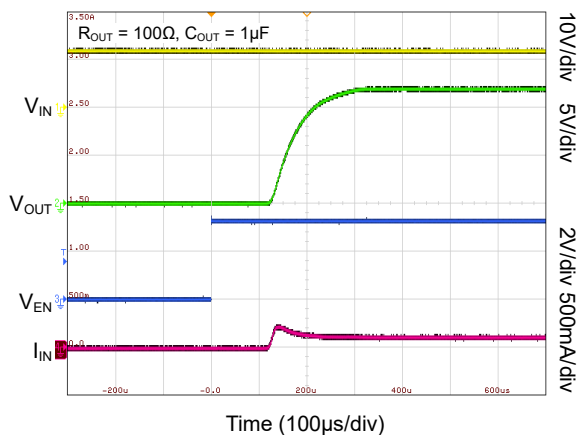
Output Voltage Ramp and Inrush Current at Start Up



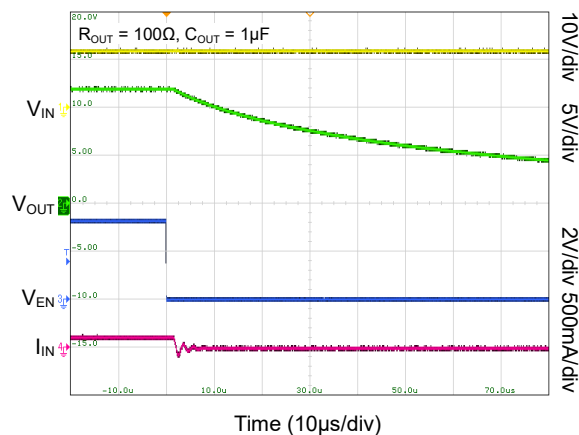
Output Voltage Ramp and Inrush Current at Start Up



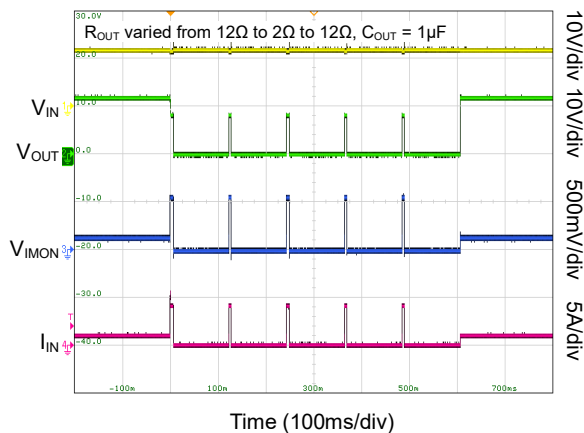
Turn-On Delay



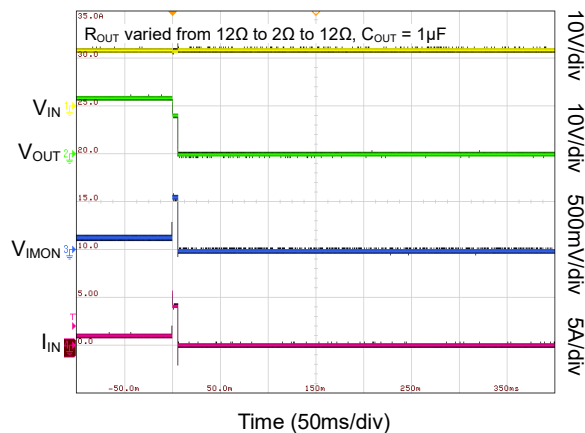
Turn-Off Delay



SGM2537A-xR/xRD/xRN Over-Current Response

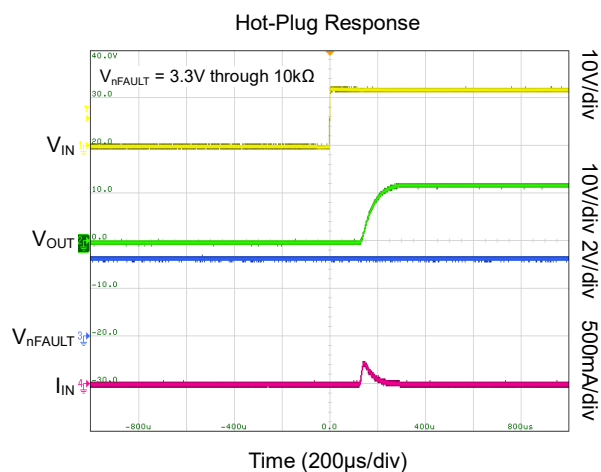
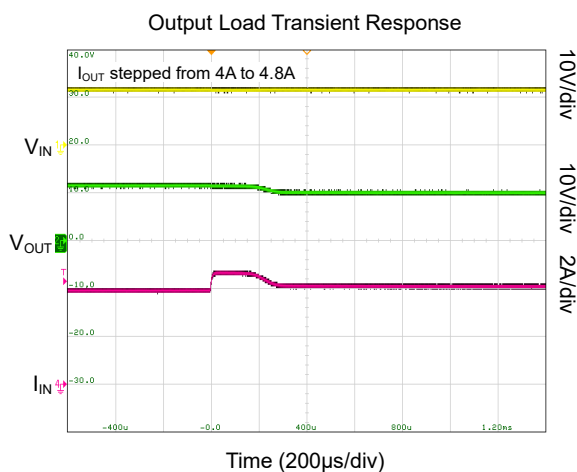
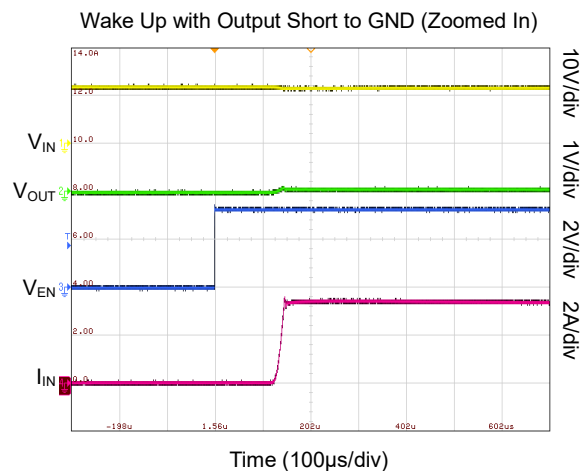
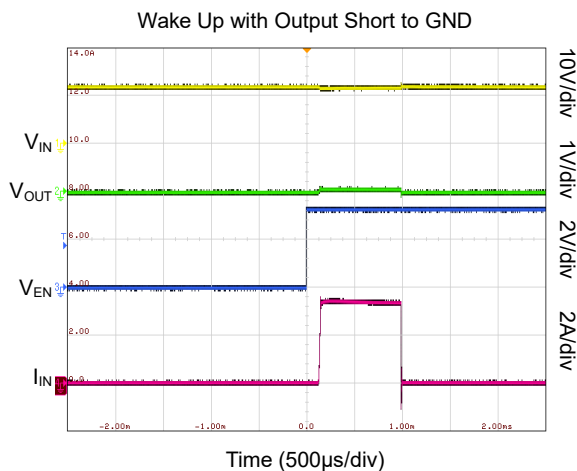
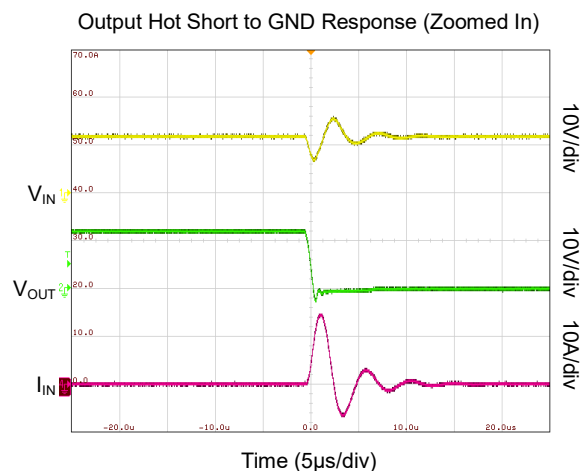
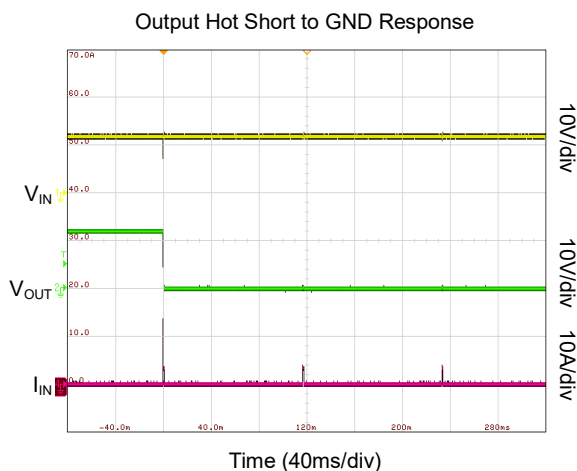


SGM2537A-xL Over-Current Response



TYPICAL PERFORMANCE CHARACTERISTICS (continued)

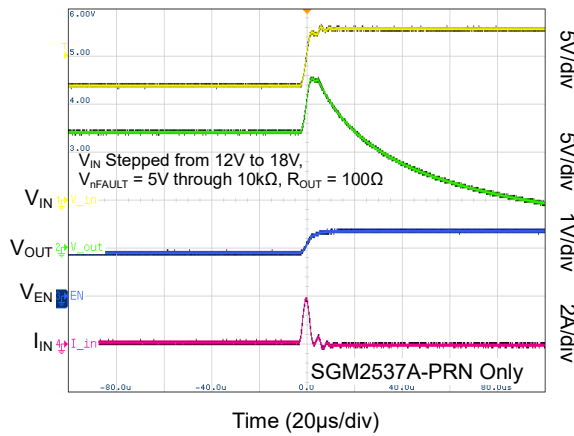
$T_A = +25^\circ\text{C}$, $V_{IN} = 12\text{V}$, $R_{LIM} = 487\Omega$, $C_{OUT} = 1\mu\text{F}$, unless otherwise noted.



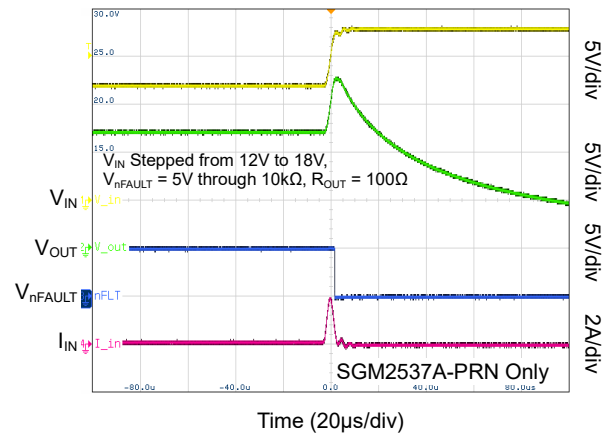
TYPICAL PERFORMANCE CHARACTERISTICS (continued)

$T_A = +25^\circ\text{C}$, $R_{LIM} = 487\Omega$, $C_{OUT} = 1\mu\text{F}$, $nFAULT = 3.3\text{V}$ through $10\text{k}\Omega$, unless otherwise noted.

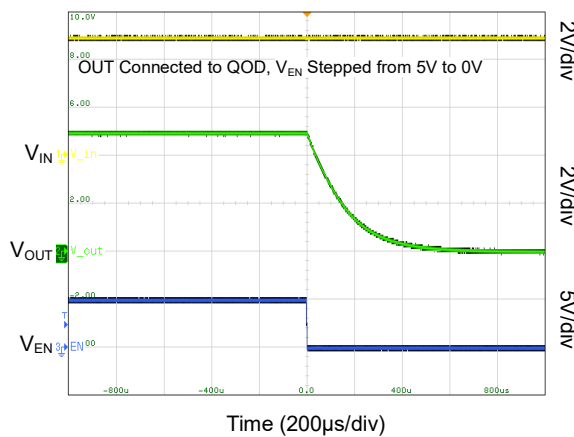
Over-Voltage Lockout Response



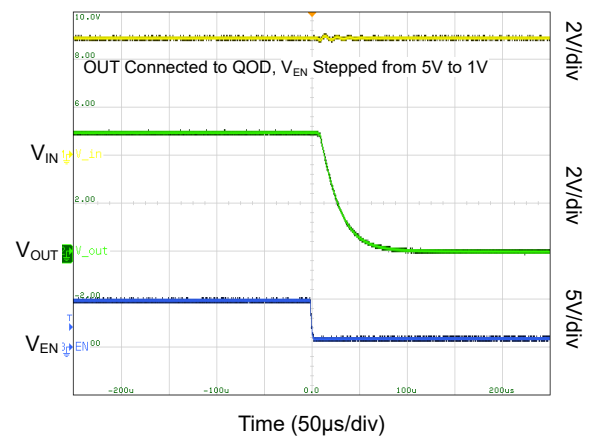
Over-Voltage Lockout nFAULT Response



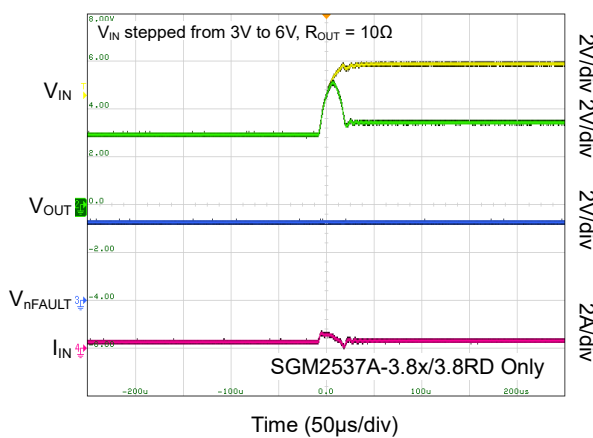
SGM2537A-5.7RD Quick Output Discharge



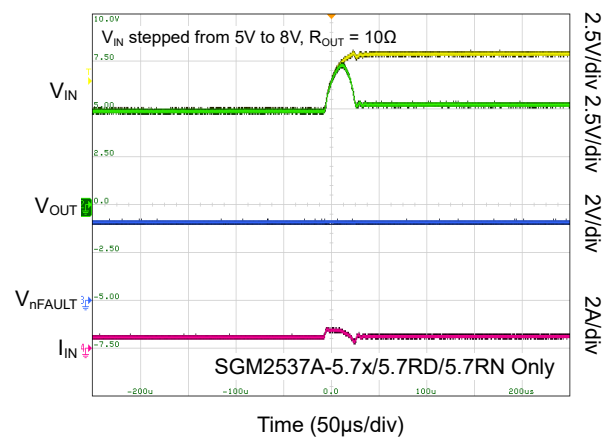
SGM2537A-5.7RD Quick Output Discharge



Over-Voltage Clamp Response

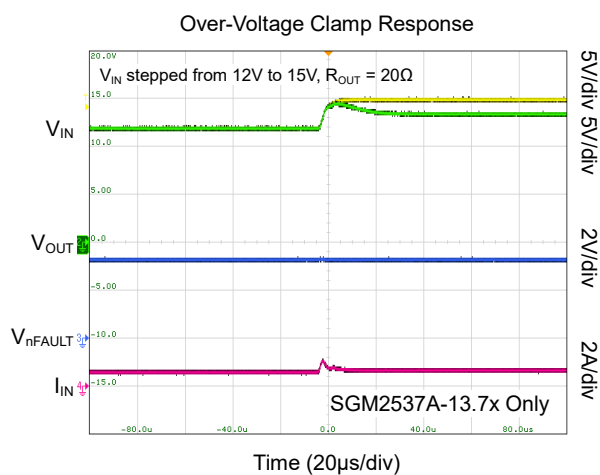


Over-Voltage Clamp Response

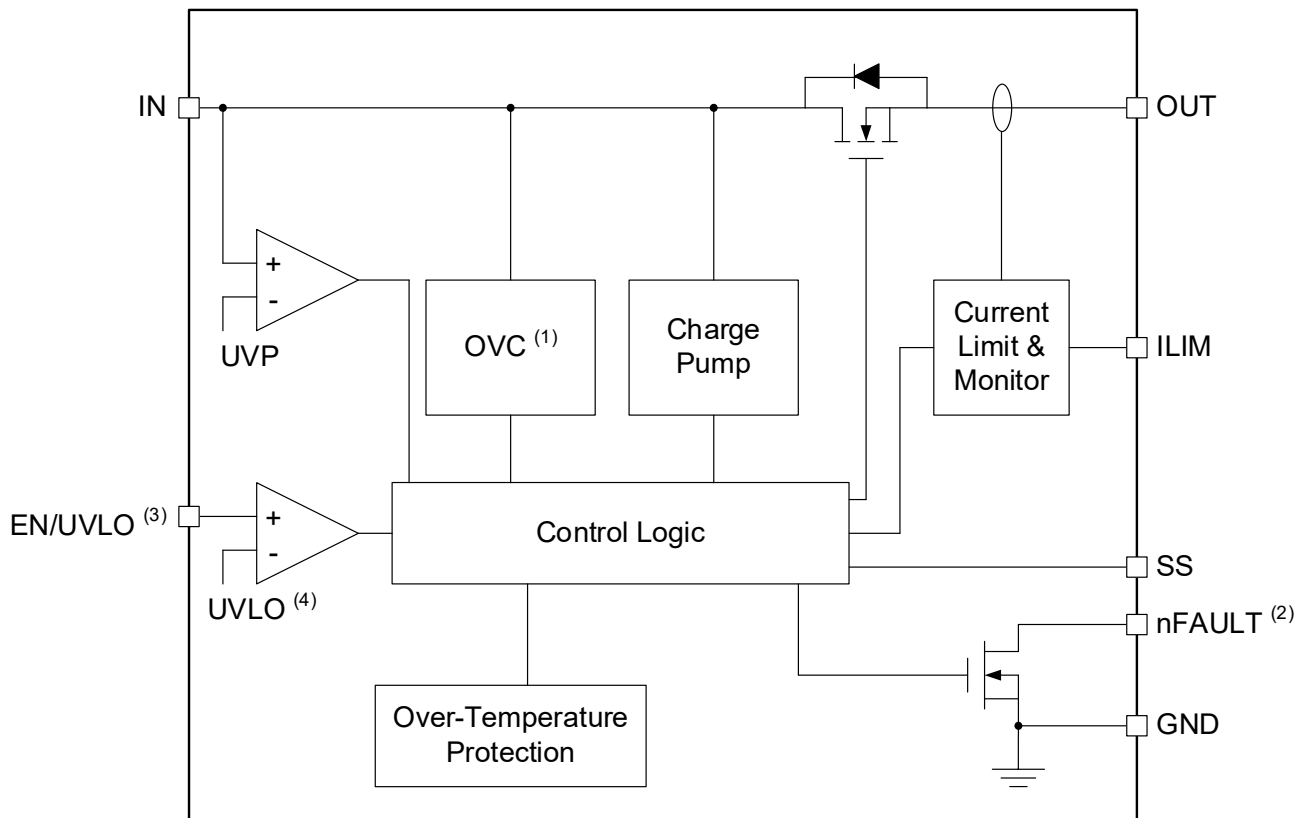


TYPICAL PERFORMANCE CHARACTERISTICS (continued)

$T_A = +25^\circ\text{C}$, $R_{\text{LIM}} = 487\Omega$, $C_{\text{OUT}} = 1\mu\text{F}$, $n\text{FAULT} = 3.3\text{V}$ through $10\text{k}\Omega$, unless otherwise noted.



FUNCTIONAL BLOCK DIAGRAM



NOTES:

1. SGM2537A-Ux/PRN does not include this block.
2. For SGM2537A-xRD, this pin is QOD.
3. For SGM2537A-xRN, this pin is nEN/OVLO.
4. For SGM2537A-xRN, this voltage is OVLO.

Figure 1. Block Diagram

DETAILED DESCRIPTION

Overview

SGM2537A is an integrated eFuse, which ensures the safety of the power delivery system due to its rich features. The device has many user- or factory-adjustable settings to suit the needs of different application scenarios. The device can be used to protect downstream equipment from input voltage fluctuations and over-current events, while a thermal shutdown mechanism is integrated to protect the device itself during fault conditions.

Under-Voltage Protection (UVP) and Under-Voltage Lockout (UVLO)

SGM2537A implements under-voltage protection at IN pin to prevent IN voltage from being too low for normal operation of system and equipment. A fixed locking threshold voltage (V_{UVP}) is provided inside the device for under-voltage protection. During start-up, if the V_{IN} voltage exceeds $V_{UVP(R)}$, the device turns on the FET. During the on-process, if the V_{IN} voltage is lower than $V_{UVP(F)}$, the device shuts down the FET. There is a hysteresis between the rising threshold and falling threshold of UVP.

For the SGM2537A, the UVLO comparator on the EN/UVLO pin can be used to set the user-adjustable under-voltage lockout threshold through the external resistance voltage divider. Figure 2 shows how to set the specific value of under-voltage lockout threshold using an external resistance voltage divider. There is a hysteresis between the rising threshold and falling threshold of UVLO.

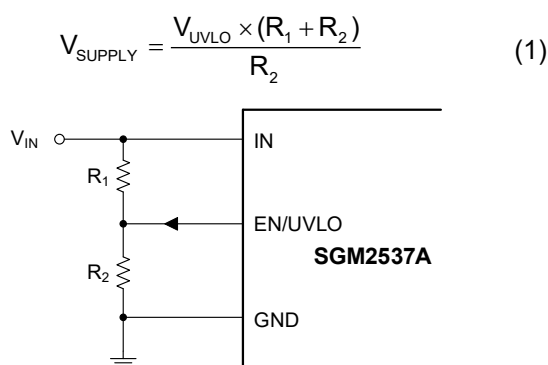


Figure 2. Under-Voltage Lockout

Over-Voltage Protection

The SGM2537A devices provide two ways to implement input over-voltage protection.

Over-Voltage Lockout (OVLO)

The SGM2537A-xRN can implement user-programmable input over-voltage threshold through an external resistor divider. When the power supply voltage exceeds a certain level, the device turns off the supply to the load. The resistance divider feeds the divided voltage of the power supply to the nEN/OVLO pin. When the voltage at the nEN/OVLO pin exceeds the threshold V_{OVLO} , the FET is disabled. When the voltage at the nEN/OVLO pin falls below the threshold, the FET is turned ON.

The user needs to determine the appropriate resistance divider in order to correctly map the over-voltage threshold of the input voltage to the internal threshold V_{OVLO} .

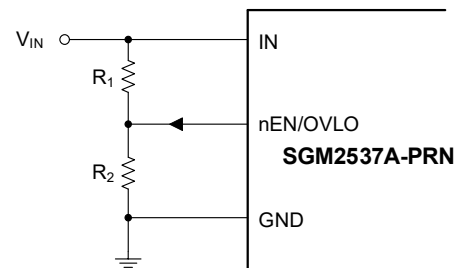


Figure 3. Over-Voltage Lockout

Over-Voltage Clamp (OVC)

The SGM2537A-3.8x/3.8RD, SGM2537A-5.7x/5.7RD/5.7RN and SGM2537A-13.7x devices provide the over-voltage clamp (OVC) function which continuously monitors the input voltage and ensures the output clamp voltage to V_{CLAMP} level within a very short time t_{OVC} once the input voltage exceeds the over-voltage clamp threshold V_{OVC} .

When the input voltage falls below the over-voltage clamp threshold V_{OVC} , the clamp will release the output voltage, which can protect the safety of output device, and continuous output clamping condition usually results in thermal shutdown as shown in Figure 4. Once the junction temperature exceeds $+156^{\circ}\text{C}$, the power MOSFET will be turned off by the thermal shutdown circuitry. For SGM2537A-xL, if the power supply or EN/UVLO is reset (pulled low and then pulled up), the device tries to turn on the power MOSFET again. For SGM2537A-xR/xRD/xRN, the device is designed with an auto-retry cycle after device temperature drops by T_{HYS} and an additional delay of t_{TSD_RST} . Unless the fault is removed, the auto-retry cycle will be continued.

DETAILED DESCRIPTION (continued)

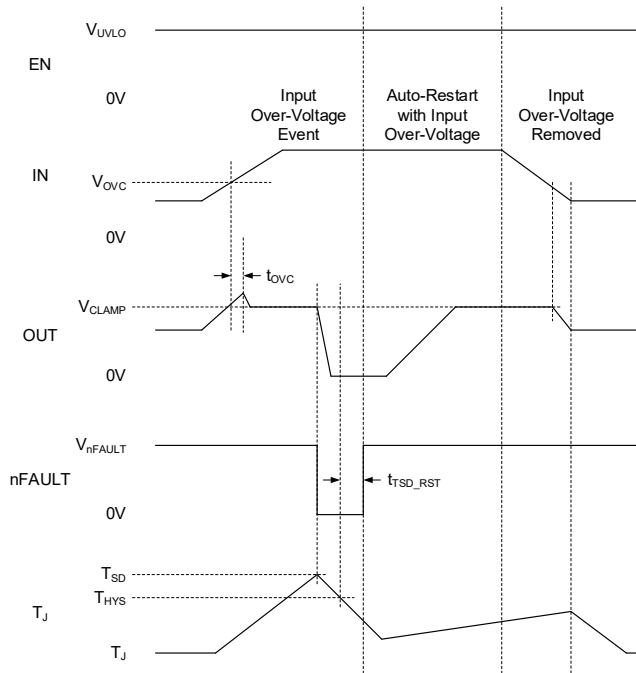


Figure 4. SGM2537A-xR/xRD/5.7RN Over-Voltage Clamp Response (Auto-Retry)

As is shown in SELECTABLE MODEL, multiple device options apply to different clamping voltage thresholds.

Inrush Current, Over-Current and Short-Circuit Protections

SGM2537A adopts three levels of forward over-current protection function:

1. Adjustable slew rate (SS) for inrush current protection.
2. Adjust threshold (I_{LIMIT}) for over-current in steady state or start-up.
3. Adjust threshold (I_{SC}) for severe over-current such as hard short-circuits in steady state or start-up.

Slew Rate and Inrush Current Control (SS)

When hot plugging or system charging large capacitive load occurs, the equipment power path will generate a large inrush current. The inrush current is proportional to the load capacitance and the output voltage slew rate. For a given load capacitance C_{OUT}, the relationship between the slew rate (SR_{ON}) and inrush current (I_{INRUSH}) is shown in Equation 2.

$$SR_{ON}(V/ms) = \frac{I_{INRUSH}(mA)}{C_{OUT}(\mu F)} \quad (2)$$

The slew rate can be controlled by connecting a capacitor at the SS pin to lower inrush current. For a given slew rate, the corresponding C_{SS} can be calculated by Equation 3.

$$C_{SS}(pF) = \frac{33000}{SR_{ON}(V/ms)} \quad (3)$$

Active Current Limit

The device will actively monitor the load current in both start-up and normal mode. When the load current rises to the over-current threshold I_{LIMIT} set by R_{ILIM}, the device adjusts the FET to restrict the load current to I_{LIMIT} in the time of t_{LIM}. When the load current falls below the current limit, the device exits the current limit. Given a desired current limit I_{LIMIT}, the value of R_{ILIM} can be calculated from Equation 4.

$$R_{ILIM} = \frac{1998}{(I_{LIMIT} - 0.03)} \quad (4)$$

During the active current limit, there is more power dissipation on the device because the output voltage drops. If the internal temperature (T_J) of the device exceeds the thermal shutdown threshold (T_{SD}), the FET will be turned off, and the device will either be latched off (SGM2537A-xL) or restarted automatically after a certain time interval (SGM2537A-xR/xRD/xRN) as shown in the OTP section.

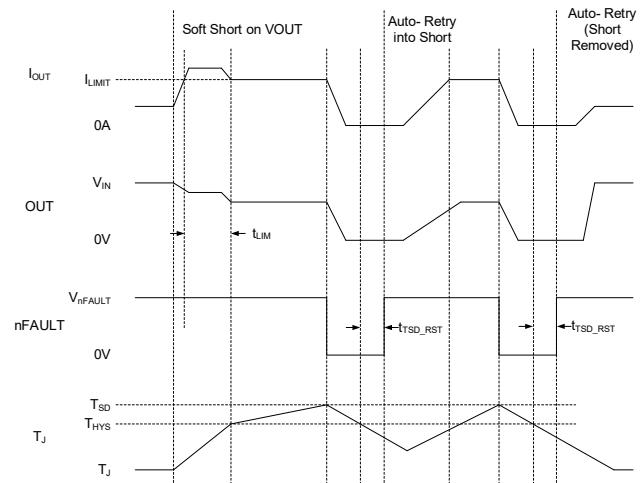


Figure 5. SGM2537A-xR/xRD/xRN Over-Current Response (Auto-Retry)

DETAILED DESCRIPTION (continued)

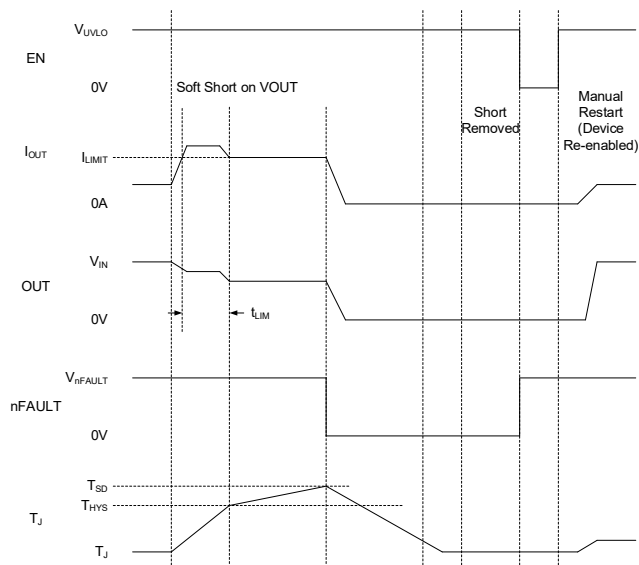


Figure 6. SGM2537A-xL Over-Current Response (Latch-Off)

Short-Circuit Protection

When a serious over-current event similar to a short-circuit event occurs, the SGM2537A triggers a fast-trip response and limits the current to I_{LIMIT} in order to prevent the system from being damaged by excessive current flowing through the device. When the current falls below the current limit I_{LIMIT} , the device exits the current limit. If the fault persists, the device continues to operate in the current limit mode, causing the internal temperature of the device to rise until the thermal shutdown. Thereafter, the device will either be latched off (SGM2537A-xL) or restarted automatically after a certain time interval (SGM2537A-xR/xRD/xRN) as shown in the OTP section.

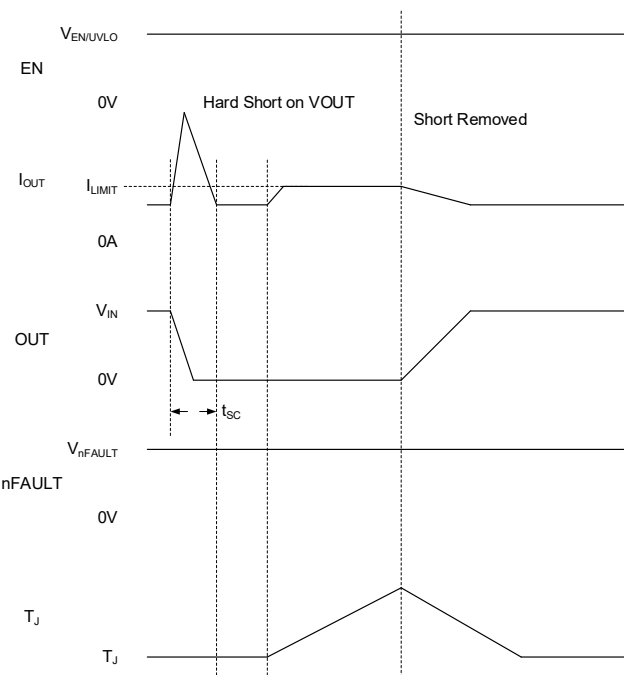


Figure 7. SGM2537A Short-Circuit Response

Over-Temperature Protection (OTP)

The SGM2537A always monitors the temperature (T_J) of the internal die. Once the internal temperature exceeds the thermal shutdown threshold (T_{SD}), the device shuts down immediately. When SGM2537A-xL triggers the thermal shutdown, it still remains in the shutdown state unless the equipment is power cycled or re-enabled. When SGM2537A-xR/xRD/xRN triggers the thermal shutdown, it remains in the shutdown state until the internal temperature of the equipment drops by T_{HYS} . After that, it will retry to turn on automatically after a t_{RST} delay time if it is still enabled. See Table 1.

Table 1. SGM2537A Thermal Shutdown

Device	Enter T_{SD}	Exit T_{SD}
SGM2537A-xL (Latch-Off)	$T_J \geq T_{SD}$	$T_J < T_{SD}$, device power cycled or re-enabled (with EN/UVLO pin)
SGM2537A-xR/xRD/xRN (Auto-Retry)	$T_J \geq T_{SD}$	$T_J < T_{SD} - T_{HYS}$, t_{SD_RST} timer expired

nFault Indication (nFAULT)

Table 2 shows the protection response of equipment under different fault conditions. The SGM2537A provides an active-low external fault indication pin.

DETAILED DESCRIPTION (continued)

Table 2. SGM2537A Fault Summary

Event/Fault	Protection Response	nFAULT Indication
Over-Temperature	Shutdown	Yes
Over-Voltage	Output Voltage Clamp (OVC) (SGM2537A-3.8x/5.7x/13.7x Only)	No
Over-Voltage	Shutdown (OVLO) (SGM2537A-xRN Only)	Yes
Under-Voltage	Shutdown (UVP or UVLO)	No
Over-Current	Current Limit	No
Short-Circuit	Current Limit	No
ILIM Pin Open	Shutdown	No
ILIM Pin Short	Shutdown ($I_{OUT} > I_{CB}$)	Yes ($I_{OUT} > I_{CB}$)

A latched fault can be cleared by power cycling (pulling V_{IN} to 0V) or re-enable.

Quick Output Discharge (QOD)

Some applications require the output capacitor to be discharged quickly when the eFuse is turned off, so that downstream devices will not take unexpected actions due to slow discharge of the output capacitor. SGM2537A-xRD internally integrates the Quick Output Discharge function, which can be enabled by connecting the OUT pin to the QOD pin. The QOD pin has an internal FET to provide a fast discharge path. Initially the FET operates in the saturation region and causes a constant current discharge in the output capacitor. The FET then operates in the linear region, where the output capacitor discharges through an equivalent resistance.

The QOD function of the chip can be equivalent to an RC discharge circuit to simplify the analysis. Among them, the discharge time of the output capacitor is the same as the charging time of the output capacitor under the same conditions. The discharge resistor RQOD is the equivalent resistance of the FET when it is used for discharge. It takes 5 times the time constant ($\tau = R \times C$) to discharge the capacitor voltage to 0.7% of the initial value. For example, when the equivalent QOD resistance is 15Ω, the time required to discharge a 100μF output capacitor from 5V to 35mV can be calculated by Equation 5.

$$t_{\text{Discharge}} = 5 \times 15\Omega \times 100\mu\text{F} = 7.5\text{ms} \quad (5)$$

Device Functional Modes

The specific characteristics of the device depend on the operation mode.

EN/UVLO and nFAULT Pins Functional Mode 1: Single Device

Self-Controlled

In this operation mode, there is no external host. The input power supply enables this device. The nFAULT pin pulls up to an external power supply and can optionally be monitored by an external host. See Figure 8.

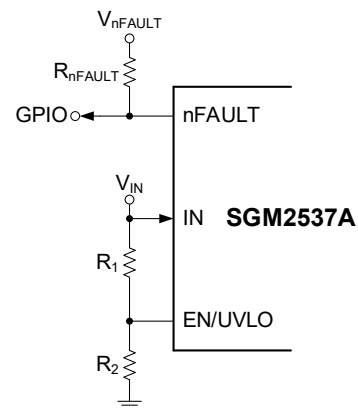


Figure 8. Single Device, Self-Controlled

Host-Controlled

In this operation mode, an external host can enable the device via a GPIO driving the EN/UVLO pin. The nFAULT pin pulls up to an external power supply and can optionally be monitored by an external host. See Figure 9.

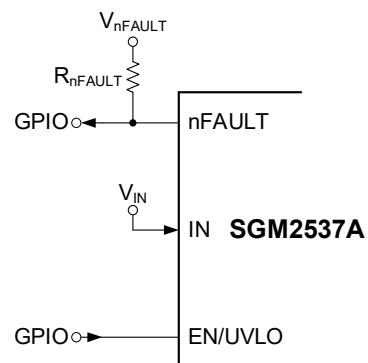


Figure 9. Single Device, Host-Controlled

DETAILED DESCRIPTION (continued)

EN/UVLO and nFAULT Pins Functional Mode 2:

Multiple Devices

Self-Controlled

In this operation mode, there is no host, so the devices are all self-controlling. EN/UVLO, nFAULT pins of no more than three devices are connected as shown in Figure 10, so that one device can automatically disable other devices when a fault event is detected.

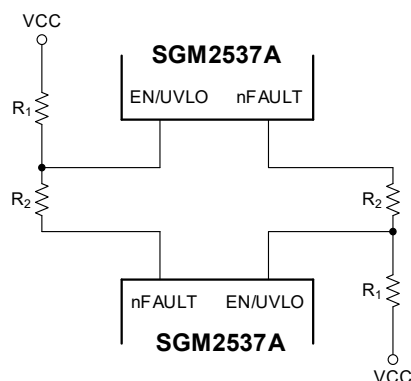


Figure 10. Multiple Devices, Self-Controlled

It should be noted that this connection method is only suitable for the active high SGM2537A-xR variants.

Figure 11 and Figure 12 are tested under the conditions of Figure 9.

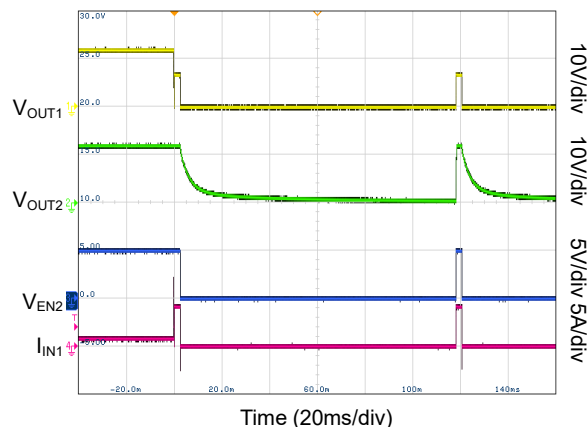


Figure 11. SGM2537A-13.7R Self-Controlled Mode Response with Overload Fault on OUT1 Followed by Auto-Retry with Persistent Fault

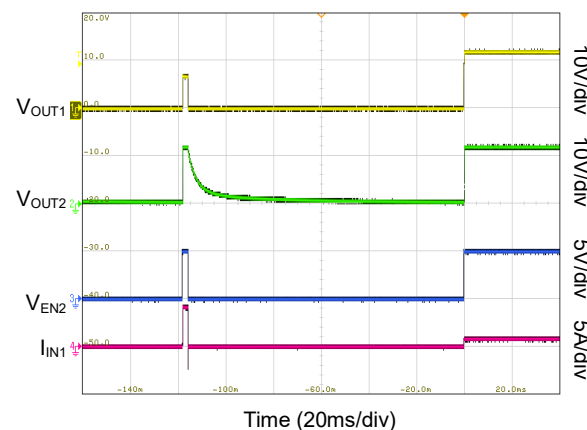
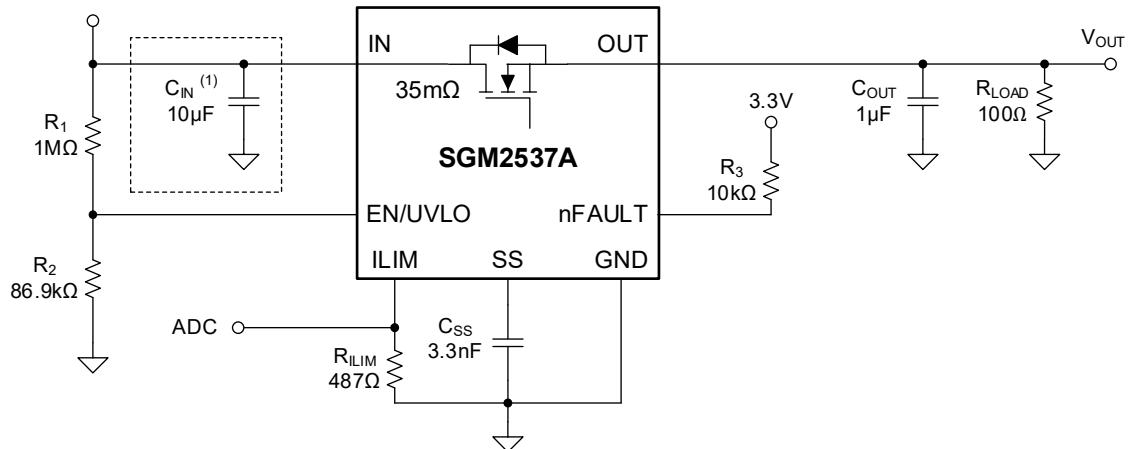


Figure 12. SGM2537A-13.7R Self-Controlled Mode Response with Overload on OUT1 Followed by Recovery with Fault Removed

APPLICATION INFORMATION

Typical Application

 $V_{IN} = 2.7V$ to $18V$ 

NOTE: 1. C_{IN} is optional. A $10\mu F$ capacitor is recommended for transient suppression from the inductance of PCB routing or input wiring.

Figure 13. Typical Application Schematic: Simple eFuse for Set-Top Boxes

Design Requirements

Table 3 shows the design requirements for the SGM2537A-13.7x.

Table 3. Design Parameters

Design Parameter	Example Value
Input Voltage, V_{IN}	12V
Under-Voltage Lockout Set Point, V_{UV}	4.3V
Over-Voltage Protection Set Point, V_{OV}	Default: $V_{OVC} = 13.7V$
Load at Start-Up, $R_{L(SU)}$	4Ω
Current Limit, I_{LIMIT}	3.7A
Load Capacitance, C_{OUT}	1μF
Maximum Ambient Temperatures, T_A	+85°C

Programming the Current Limit Threshold: R_{ILIM} Selection

The over-current threshold can be set by the resistor R_{ILIM} connected to the ILIM pin, and its value can be calculated by Equation 6:

$$R_{ILIM} = \frac{1998}{(I_{LIMIT} - 0.03)} \quad (6)$$

For $I_{LIMIT} = 3.7A$, according to Equation 5, $R_{ILIM} = 544\Omega$. Using the closest standard 1% resistor values, $R_{ILIM} = 549\Omega$ is chosen.

Under-Voltage Lockout Set Point

The supply under-voltage lockout (UVLO) threshold is set by a resistor divider connected to the EN/UVLO pin. This threshold can be calculated from Equation 7:

$$V_{UV} = \frac{R_1 + R_2}{R_2} \times V_{UVLO_R} \quad (7)$$

Where V_{UVLO_R} is the rising threshold (1.2V) of the EN/UVLO pin. R_1 and R_2 are the resistors of the resistor divider. Since R_1 and R_2 cause additional leakage current to flow out of the input voltage, their values need to be taken into account for the acceptable leakage current of the system. The leakage current flowing through R_1 and R_2 from the supply is $I_{R12} = V_{IN}/(R_1 + R_2)$. Considering that an external active device connected to a resistor divider causes additional leakage current, this increases the calculation error of the supply under-voltage threshold. Therefore, the leakage current flowing through R_1 and R_2 (I_{R12}) should be greater than 20 times the leakage current expected by the EN/UVLO pin.

According to the application scenario requirements, $V_{UVR} = 4.3V$. Given $R_1 = 1M\Omega$, $R_2 = 387k\Omega$ can be obtained according to the above equation.

APPLICATION INFORMATION (continued)

Setting Output Voltage Ramp Time (t_{SS})

During the design process, it must be ensured that the junction temperature of the device does not meet the thermal shutdown threshold under either start-up or steady-state conditions. Given that the power stress to which the device is subjected at start-up is typically an order of magnitude greater than under steady-state conditions, the determination of start-up time and inrush current limit is particularly important to avoid thermal shutdown at start-up. There are two possible cases to discuss during start-up:

Case 1: Start-Up without Load. Output Capacitance Draws Current

During start-up, the voltage stress of the FET decreases as the output capacitor voltage increases. Use Equation 8 to calculate the average power dissipated on the device.

$$P_{D(INRUSH)} = 0.5 \times V_{IN} \times I_{INRUSH} \quad (8)$$

Given the output voltage rise time, the inrush current can be calculated from Equation 9.

$$I_{INRUSH} = C_{OUT} \times \frac{V_{IN}}{t_{SS}} \quad (9)$$

The prerequisite for Equation 8 is that no load current is generated until the output voltage rises to V_{IN} .

Case 2: Start-Up with Load. Output Capacitance and Load Draw Current

If the load keeps drawing current from the power supply during start-up, the power dissipated on the device will be greater. Assuming that the system has a resistive load, Equations 10 to 13 give the power dissipated by the resistive load during the start-up of the device.

$$P_{D(LOAD)} = \left(\frac{1}{6}\right) \times \frac{V_{IN}^2}{R_{L(SU)}} \quad (10)$$

The total power dissipated during the start-up phase can be calculated by Equation 11.

$$P_{D(STARTUP)} = P_{D(INRUSH)} + P_{D(LOAD)} \quad (11)$$

The total current during the start-up phase can be calculated by Equation 12.

$$I_{STARTUP} = I_{INRUSH} + I_L(t) \quad (12)$$

If the total current during start-up exceeds I_{LIMIT} , the current is limited to I_{LIMIT} . Use Equation 13 to calculate the current-limited charging time.

$$t_{SS(Current-Limited)} = C_{OUT} \times R_{L(SU)} \times \left[\frac{I_{LIMIT}}{I_{INRUSH}} - 1 + \ln \left(\frac{I_{INRUSH}}{I_{LIMIT} - \frac{V_{IN}}{R_{L(SU)}}} \right) \right] \quad (13)$$

For $C_{SS} = \text{Open}$, the slew rate is 85mV/μs, and the rising time t_{SS} for 12V input is 112μs.

Use Equation 14 to calculate the current drawn by the output capacitor during ramp-up.

$$I_{INRUSH} = \frac{1\mu F \times 85mV}{1\mu s} = 85mA \quad (14)$$

The dissipated power can be calculated by Equation 15.

$$P_{D(INRUSH)} = 0.5 \times 12 \times 85mW = 510mW \quad (15)$$

Thermal Shutdown Time vs. Power Dissipation shows that for 510mW, $T_A = +85^\circ C$, the device thermal shutdown time is infinite, which is much larger than the output rise time $t_{SS} = 112\mu s$. Therefore, setting the output rise time to 5ms has no negative impact on device security. Therefore, it is safe to use 112μs as the startup time without any load on the output.

The additional power dissipated during start-up due to a 4Ω resistive load can be calculated from Equation 10.

$$P_{D(LOAD)} = \frac{12 \times 12}{6 \times 4} = 6W \quad (16)$$

The total power dissipated during start-up can be calculated by Equation 17.

$$P_{D(STARTUP)} = 6W + 510mW = 6.51W \quad (17)$$

Thermal Shutdown Time vs. Power Dissipation shows that for 6.51W, $T_A = +85^\circ C$, the device thermal shutdown time is more than 20ms, which is within the acceptable limits to avoid using an external capacitor C_{SS} with a 4Ω load. If the output capacitor C_{OUT} is large, it is recommended to increase the capacitance of C_{SS} to reduce the power dissipation.

APPLICATION INFORMATION (continued)

Support Component Selection: C_{IN}

A ceramic capacitor in the range from 0.1μF to 10μF is connected near the input pin to absorb and suppress transient voltage spikes and ringing.

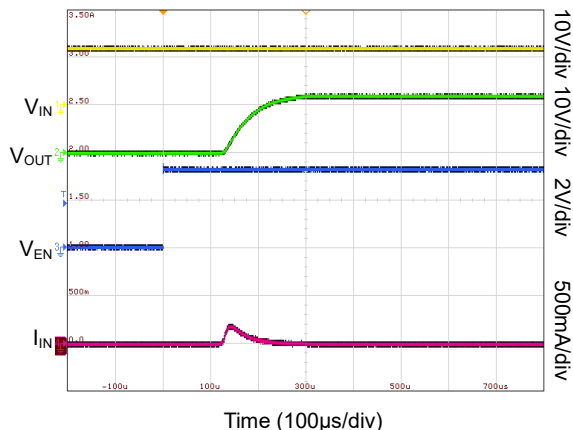


Figure 14. Output Ramp without Any Load

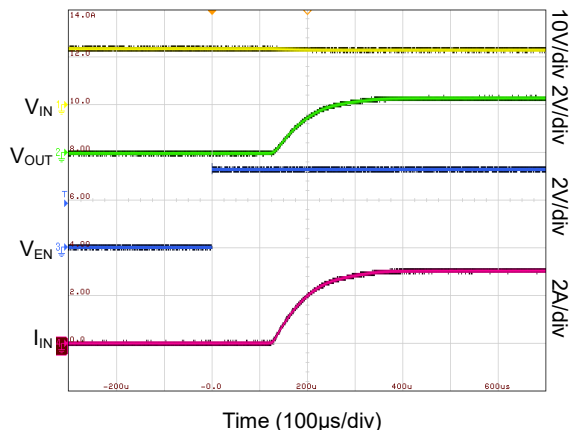


Figure 15. Output Ramp with 4Ω Load at Start-Up

Quick Output Discharge Using SGM2537A-xRD

When the SGM2537A-xRD is disabled, the internal FET is turned off and the OUT pin is left floating, where the OUT voltage drop process is determined by the external load. In some applications, this can cause downstream equipment to be in an unpredictable state because the OUT voltage is in an undesired state. Connect the QOD pin to the OUT pin to realize the Fast Output Discharge function of the SGM2537A-xRD, as shown in Figure 16. When the SGM2537A-xRD is disabled via EN, the QOD pin is pulled low and provides a fast discharge path for the output capacitor. The output voltage discharge rate is determined by the output capacitance, the total resistance of the discharge path (internal plus external), and the external load.

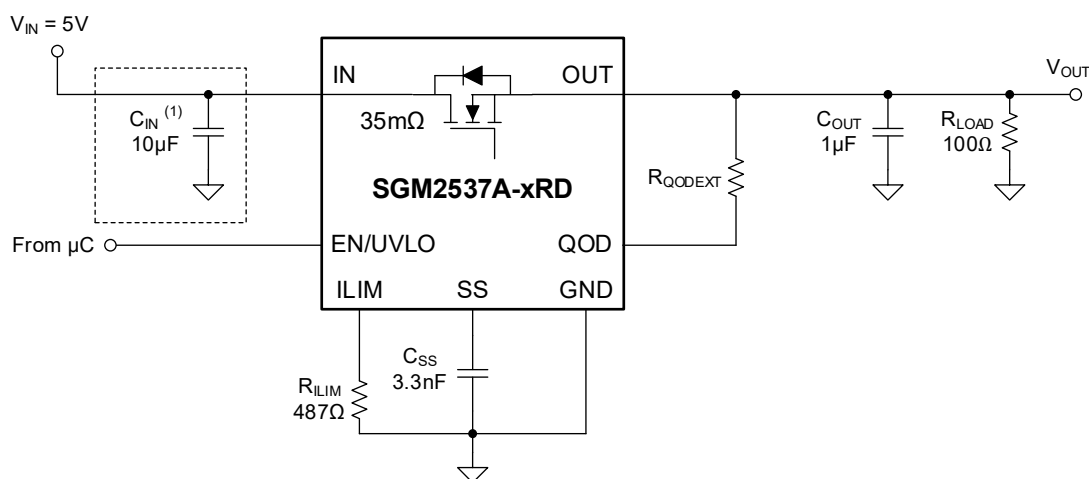


Figure 16. Circuit Implementation with Quick Output Discharge Function Using SGM2537A-xRD

APPLICATION INFORMATION (continued)

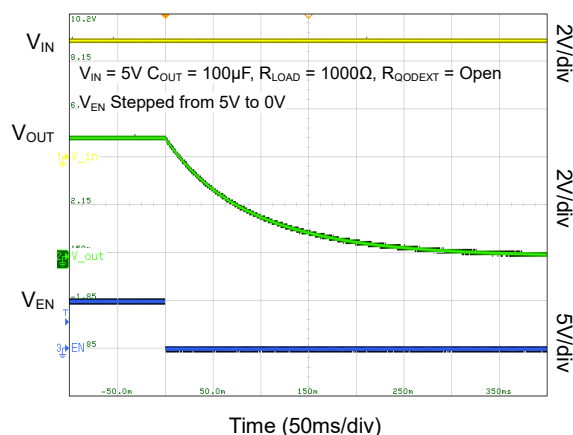


Figure 17. Output Voltage Discharge Using SGM2537A-5.7RD without QOD

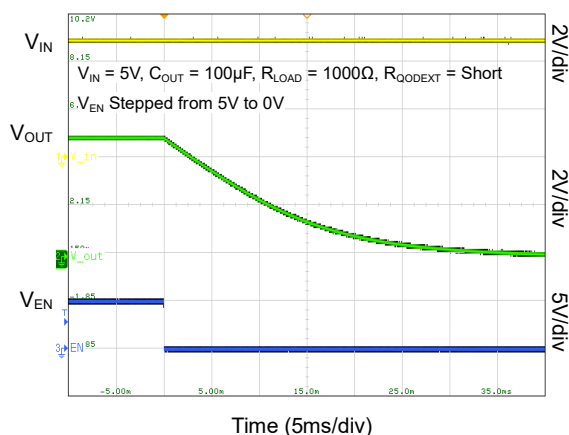


Figure 18. Output Voltage Discharge Using SGM2537A-5.7RD with QOD

Over-Voltage Lockout Using SGM2537A-PRN

The SGM2537A-PRN implements the input over-voltage protection via a resistor divider circuit, which is connected from the supply to the nEN/OVLO pin to GND (as shown in Figure 19) to achieve a programmable over-voltage threshold. When the divided voltage on the nEN/OVLO exceeds V_{OVLO} , the device turns off the internal FET and protects the downstream load.

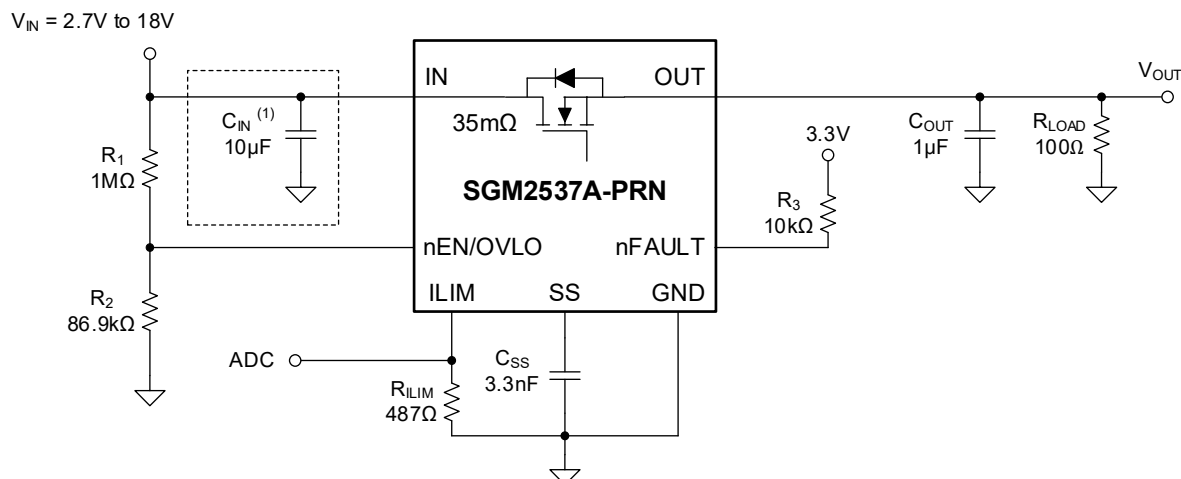


Figure 19. Circuit Implementation for Over-Voltage Lockout Using SGM2537A-PRN

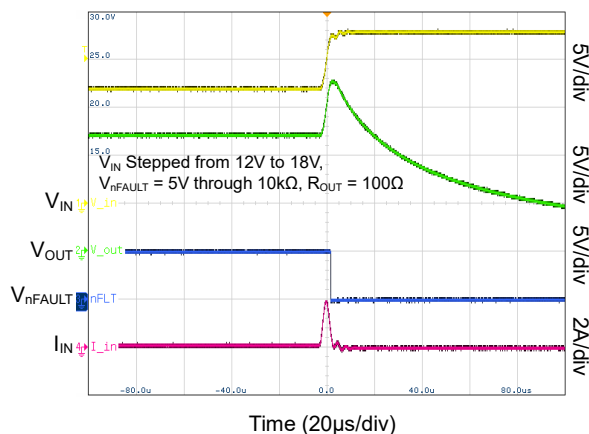


Figure 20. Over-Voltage Lockout Response Using SGM2537A-PRN

APPLICATION INFORMATION (continued)

Power Supply Recommendations

The SGM2537A devices are suitable for a supply voltage from 2.7V to 18V. If the input supply is more than a few inches away from the device, it is recommended to place an input bypass ceramic capacitor greater than 0.1μF. The rated current of the power supply must be greater than the over-current threshold set by the device, otherwise the supply voltage will drop in the event of an over-current or short-circuit.

Transient Protection

In the case of a short-circuit or over-current limit, the device may cut off the current, and due to the parasitic inductance in series at the input and output of the device, a positive voltage spike will occur at the input and output, and a negative voltage spike will occur at the output. The amplitude of the voltage spike is determined by the parasitic inductance. These transients can cause the voltage on the device pins to exceed their maximum absolute rating if the following measures are not taken:

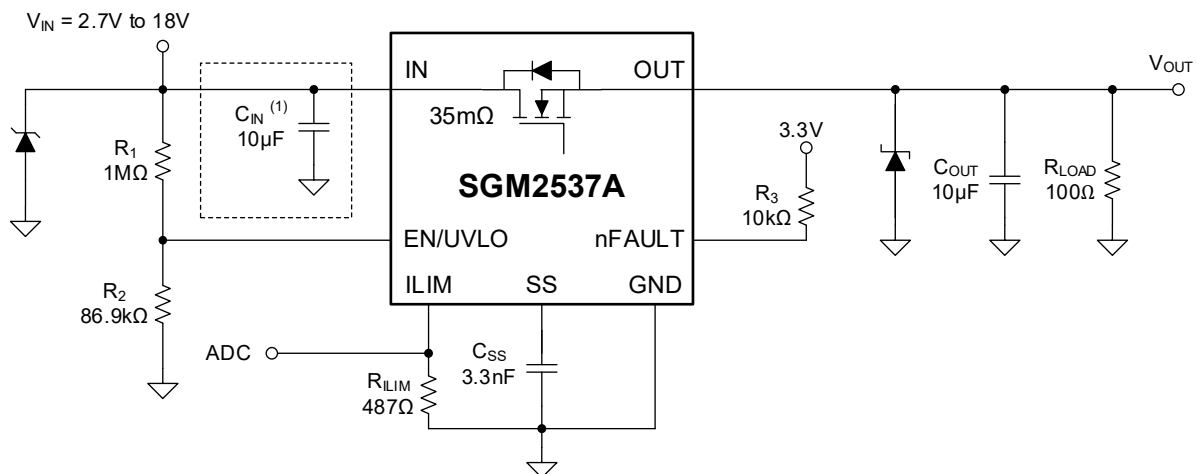
- The length of the wires at the input and output of the device is as small as possible.
- A TVS diode is paralleled at the input port of the device to absorb a positive voltage spike, and a Schottky diode is connected in parallel to the output port to absorb a negative voltage spike.
- Choose a large PCB GND plane.
- Connect a low ESR ceramic capacitor larger than 10μF near the output pin.
- A ceramic capacitor greater than 10μF is connected near the input pin to absorb and suppress transient voltage spikes and ringing.

Use Equation 18 to calculate the input capacitance value.

$$V_{\text{SPIKE}}(\text{Absolute}) = V_{\text{IN}} + I_{\text{LOAD}} \times \sqrt{\frac{L_{\text{IN}}}{C_{\text{IN}}}} \quad (18)$$

Where V_{IN} is the rating of the input voltage, I_{LOAD} is the load current, L_{IN} is the effective inductance seen looking into the source, and C_{IN} is the capacitance of the input.

Figure 21 shows a circuit implementation with optional protection components.



NOTE: 1. C_{IN} is optional. A 10μF capacitor is recommended for transient suppression from the inductance of PCB routing or input wiring.

Figure 21. Circuit Implementation with Optional Protection Components

APPLICATION INFORMATION (continued)

Output Short-Circuit Measurements

The output short-circuit waveform may be affected by factors such as input leads, power supply bypass, layout, device selection, circuit location, and output short-circuit method. It is difficult to obtain repeatable and similar output short-circuit test results. Therefore, the short-circuit results in this datasheet are for informational purposes only. Different short-circuit test results may be achieved because of different test conditions.

Layout Guidelines

- In any application, it is recommended to connect a 0.1μF or greater decoupling capacitor between IN and GND. This decoupling capacitor should be as close as possible to the IN and GND pins to minimize the area of the IN-decoupling capacitor-GND loop.
- The power path should be as wide and short as possible, with a current-carrying capacity of more than twice the device's current limit.
- The GND pin of the device must be connected to PCB ground which is a copper plane or island as short as possible.
- In order to achieve the accuracy of the eFuse function, it is recommended to provide the eFuse with a ground plane that does not flow through large currents. The ground plane of the device is connected to the ground plane of the system via a star connection.
- External components of the device as follows should be placed as close to the corresponding pins as possible:
 1. R_{ILIM}
 2. C_{SS}
 3. Resistor dividers of EN/UVLO
- The other end of these components is connected to ground via the shortest possible path. The ILIM pin should have a parasitic capacitance of less than 50pF, and the connection path of this pin should be away from the switching signal.
- Protection components such as TVS, snubbers, capacitors or Schottky diodes should be connected to the device via a short path to avoid large line inductance. It is important to note that the loop area formed by the protection components should be as small as possible.

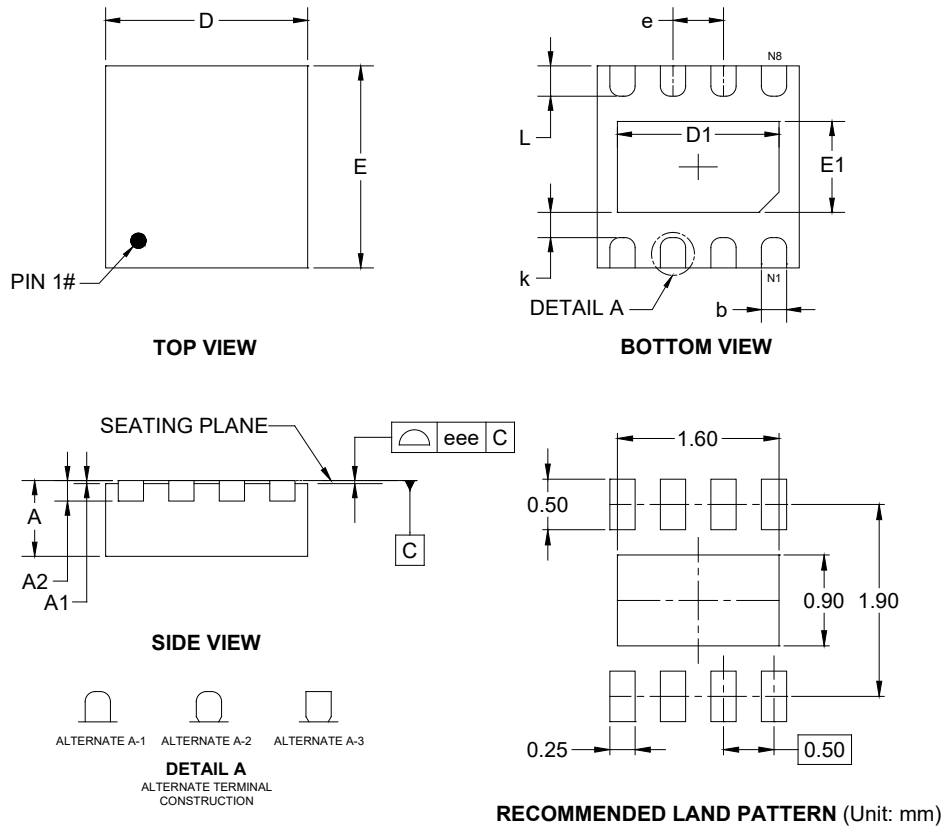
REVISION HISTORY

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

APRIL 2025 - REV.A to REV.A.1	Page
Added UL Recognized Component (File No. E532373*).....	1
Updated Application Information.....	21, 23, 24, 25
<hr/>	
Changes from Original (JULY 2024) to REV.A	Page
Changed from product preview to production data.....	All

PACKAGE OUTLINE DIMENSIONS

TDFN-2×2-8AL



Symbol	Dimensions In Millimeters		
	MIN	NOM	MAX
A	0.700	-	0.800
A1	0.000	-	0.050
A2	0.203 REF		
b	0.200	-	0.300
D	1.900	-	2.100
D1	1.450	-	1.700
E	1.900	-	2.100
E1	0.750	-	1.000
k	0.200	-	-
e	0.500 BSC		
L	0.200	-	0.400
eee	0.080		

NOTE: This drawing is subject to change without notice.

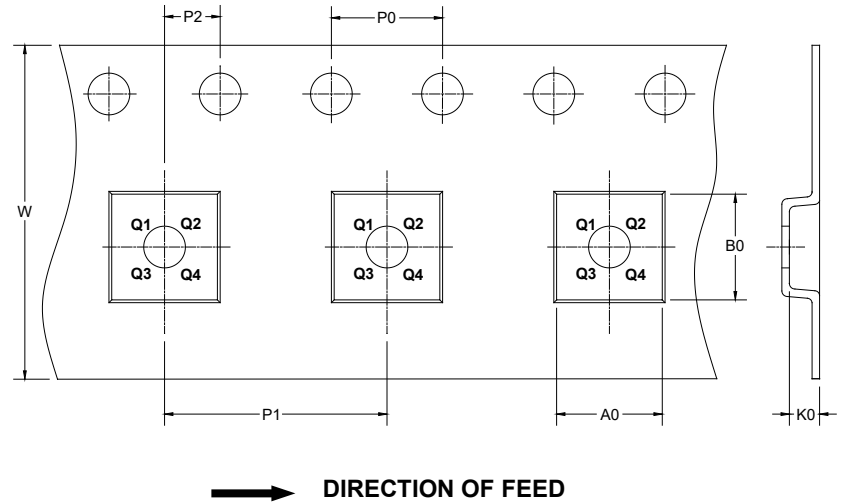
PACKAGE INFORMATION

TAPE AND REEL INFORMATION

REEL DIMENSIONS



TAPE DIMENSIONS



NOTE: The picture is only for reference. Please make the object as the standard.

KEY PARAMETER LIST OF TAPE AND REEL

Package Type	Reel Diameter	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P0 (mm)	P1 (mm)	P2 (mm)	W (mm)	Pin1 Quadrant
TDFN-2×2-8AL	7"	9.5	2.30	2.30	1.10	4.0	4.0	2.0	8.0	Q2

DD00001

PACKAGE INFORMATION

CARTON BOX DIMENSIONS



NOTE: The picture is only for reference. Please make the object as the standard.

KEY PARAMETER LIST OF CARTON BOX

Reel Type	Length (mm)	Width (mm)	Height (mm)	Pizza/Carton
7" (Option)	368	227	224	8
7"	442	410	224	18

DD0002